

Siegman Laser School 2016
24-29 July 2016
ICFO-Barcelona

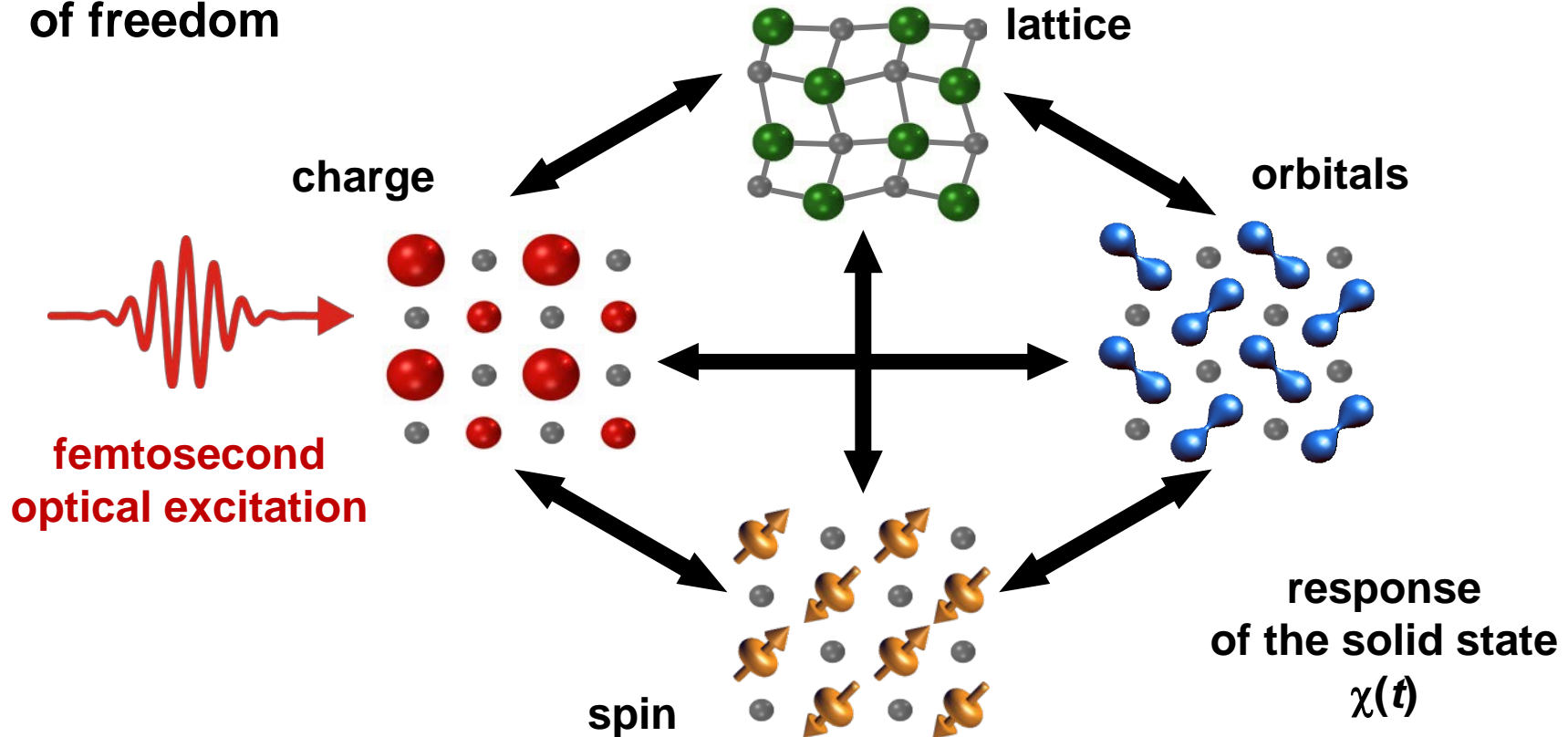
Ultrafast Laser Spectroscopy and Applications to Dynamics at Interfaces and Solids

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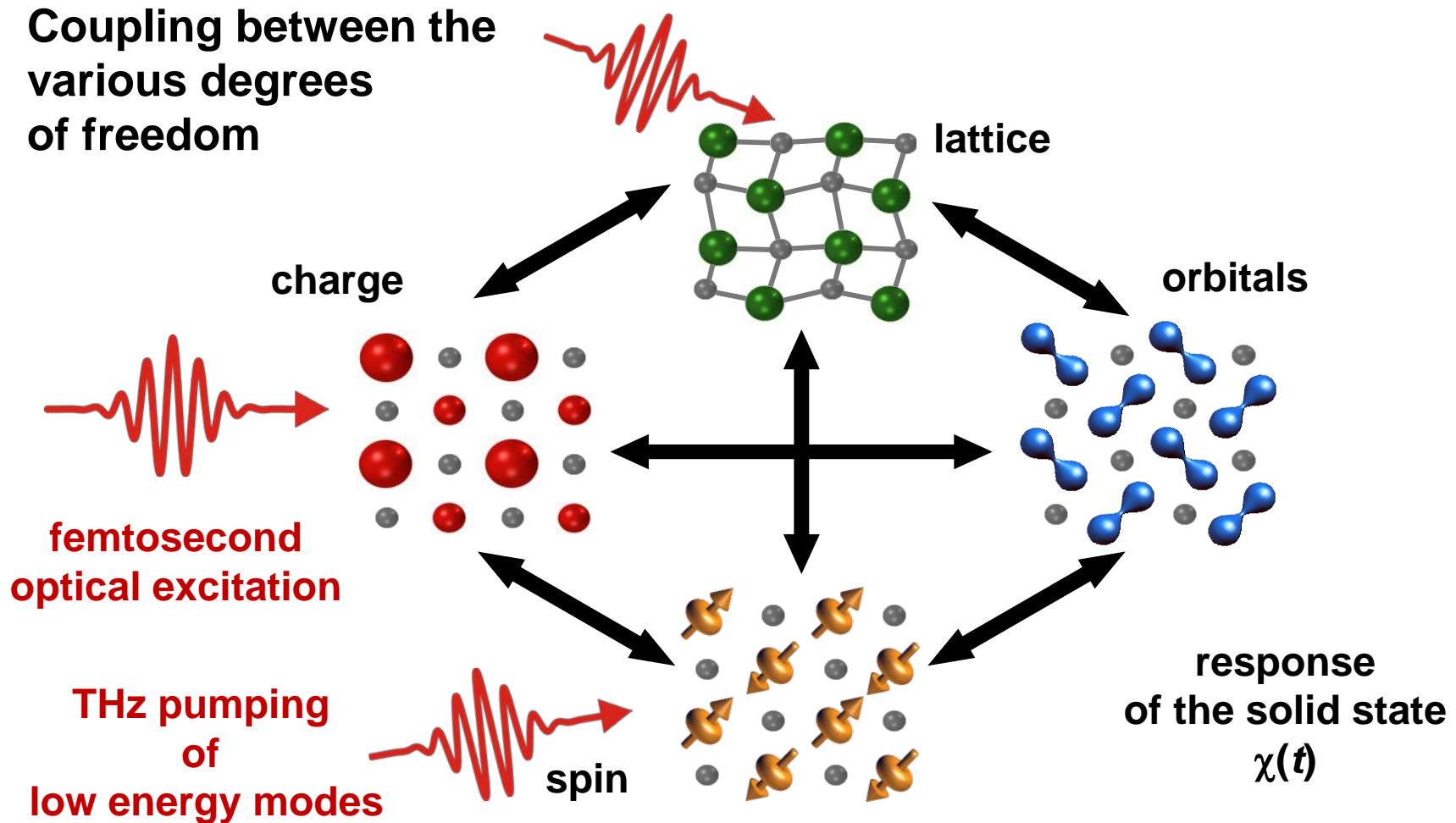
Motivation: Elementary interactions in solids

Coupling between the various degrees of freedom



Goal: Mechanistic understanding of the coupling and energy flow between the subsystems governing ultrafast phenomena

Motivation: Elementary interactions in solids



Goal: Mechanistic understanding of the coupling and energy flow between the subsystems governing ultrafast phenomena

Can phonon pumping induce phase transitions ?

Phase transitions in solids induced by optical phonon pumping

Control of the electronic phase of a manganite by mode-selective vibrational excitation

Matteo Rini¹, Ra'anan Tobey², Nicky Dean², Jiro Itatani^{1,3}, Yasuhide Tomioka⁴, Yoshinori Tokura^{4,5}, Robert W. Schoenlein¹ & Andrea Cavalleri^{2,6}

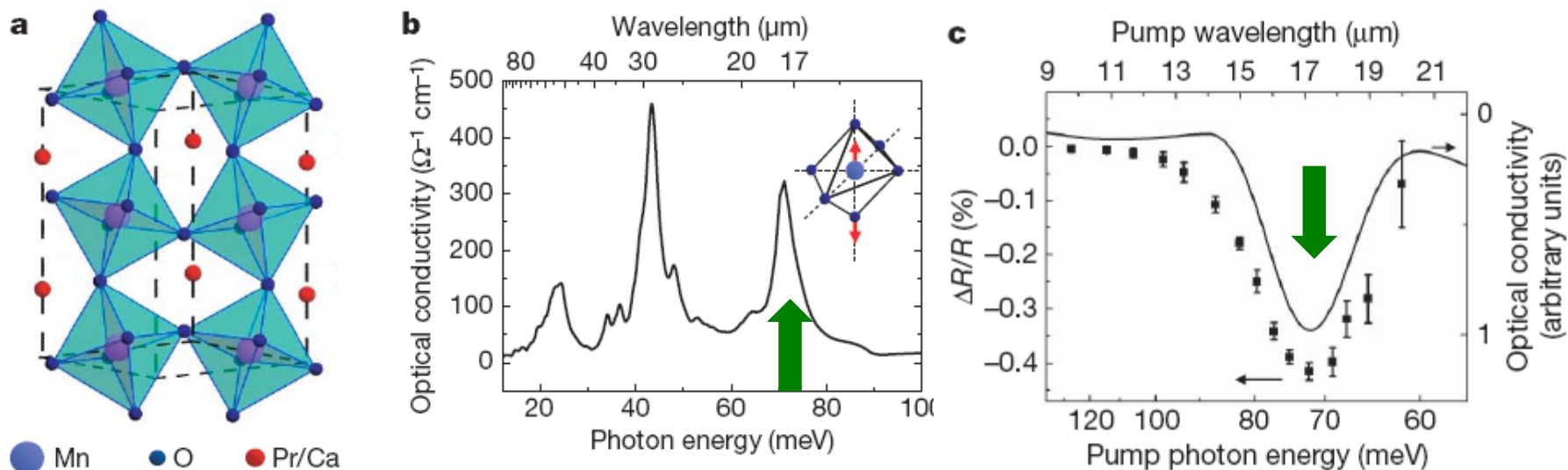


Figure 1 | $\text{Pr}_{0.7}\text{Ca}_{0.3}\text{MnO}_3$ crystal structure and vibrational spectrum.

Insulator-to-metal transition driven by resonant phonon excitation

M. Rini *et al.*, Nature **449**, 73 (2007)

Driving material response by intense THz fields

- Excitation of magnons in NiO by a THz magnetic field pulse
- Two photon excitation and phase control of a Raman active mode in diamond

How to control spins as fast as possible?

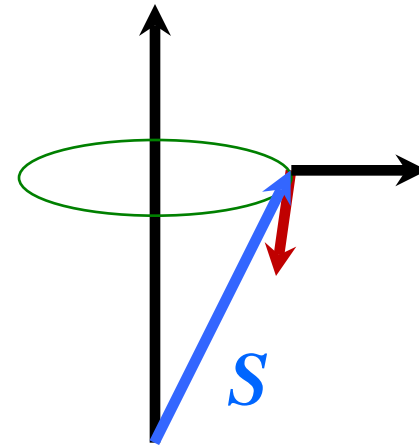
most natural stimulus: magnetic field $B(t)$

⇒ Zeeman torque

$$T = \gamma S \times (B_{\text{int}} + B)$$

most efficient coupling at resonance:

Larmor frequency $\omega_L = \gamma |B_{\text{int}}|$



ferromagnets: < 10 GHz,

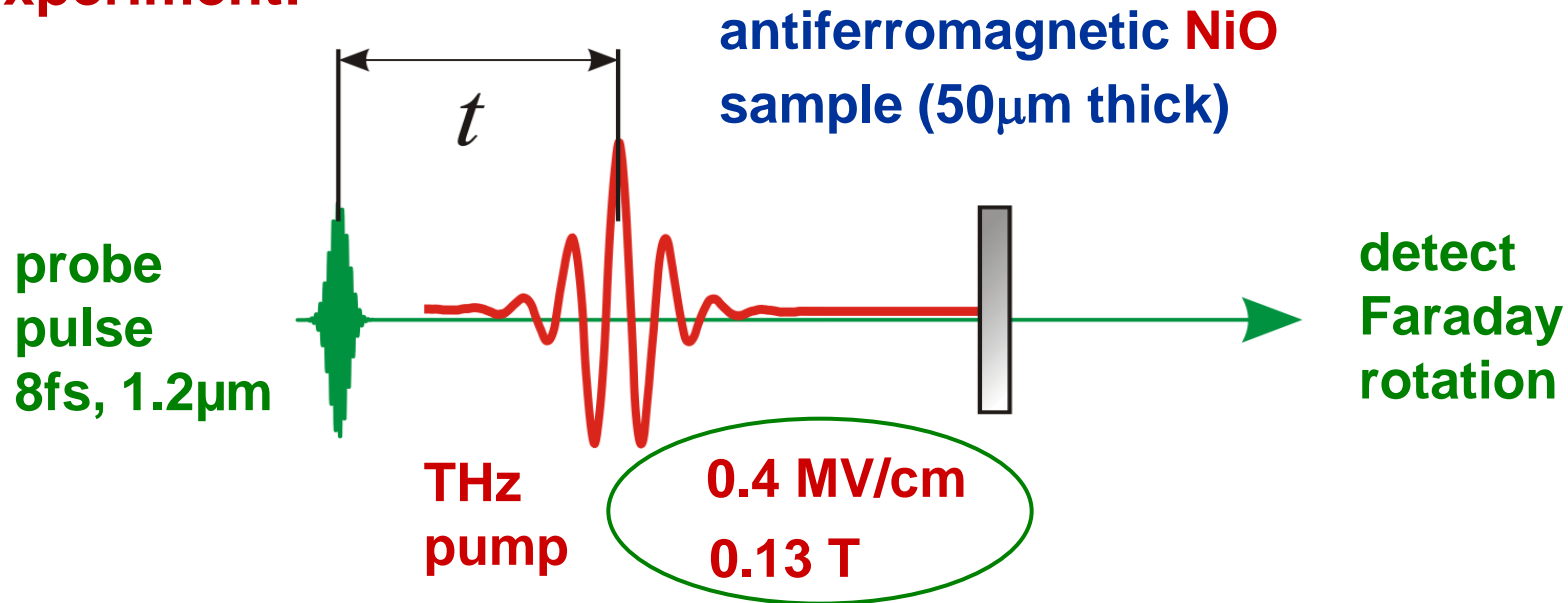
antiferromagnets: ~ 1 THz

Hiebert, Freeman, PRL (1997)

⇒ apply strong THz **magnetic field** pulse to antiferromagnet

Experiment: THz pump – infrared probe

Experiment:

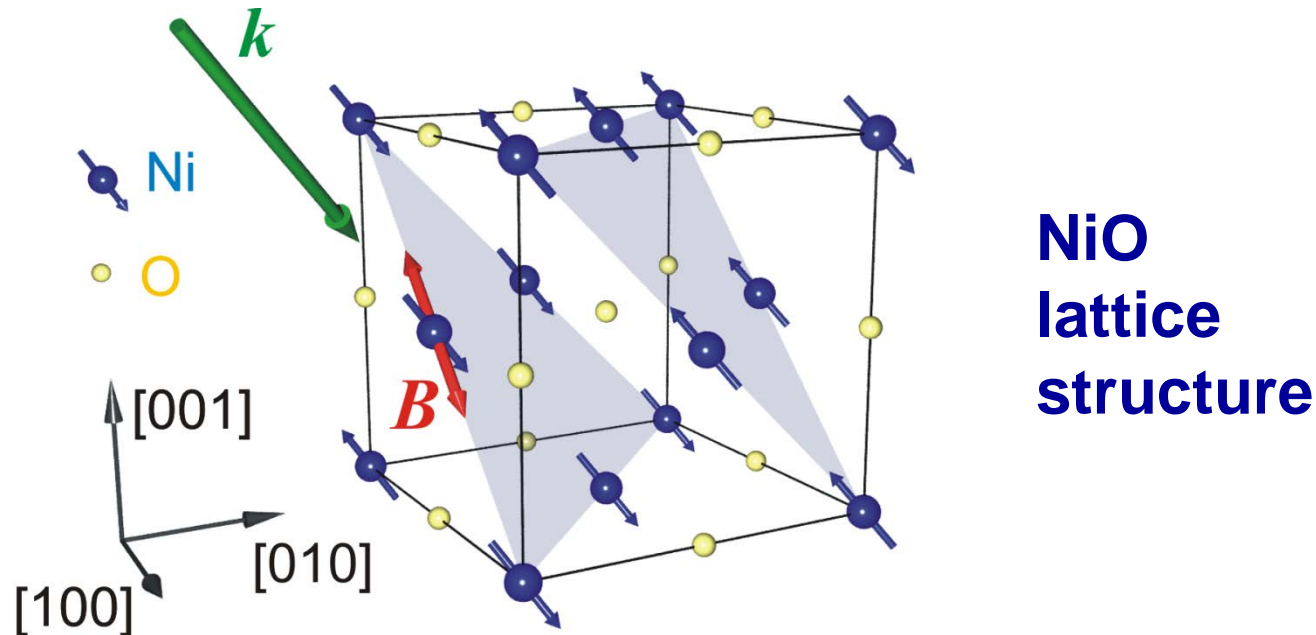


Idea:

THz **magnetic** field pulse induces transient magnetization which is detected via Faraday rotation of optical probe pulse

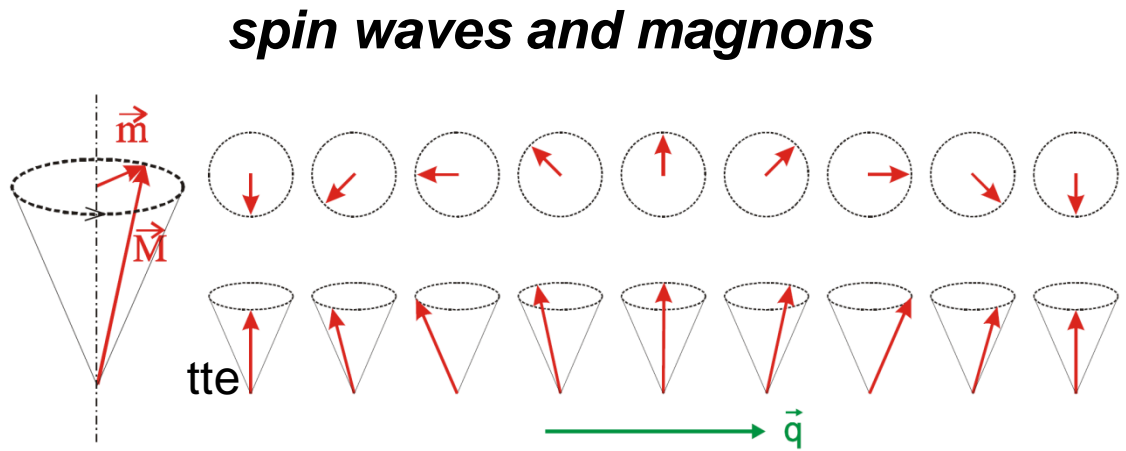
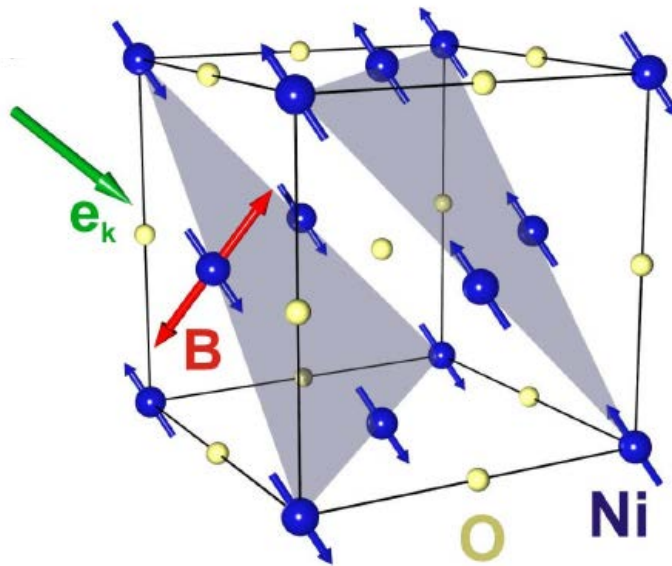
realized for ferromagnets below 10 GHz see e.g. Hiebert, Freeman, PRL (1997)

NiO: A 'textbook' antiferromagnet

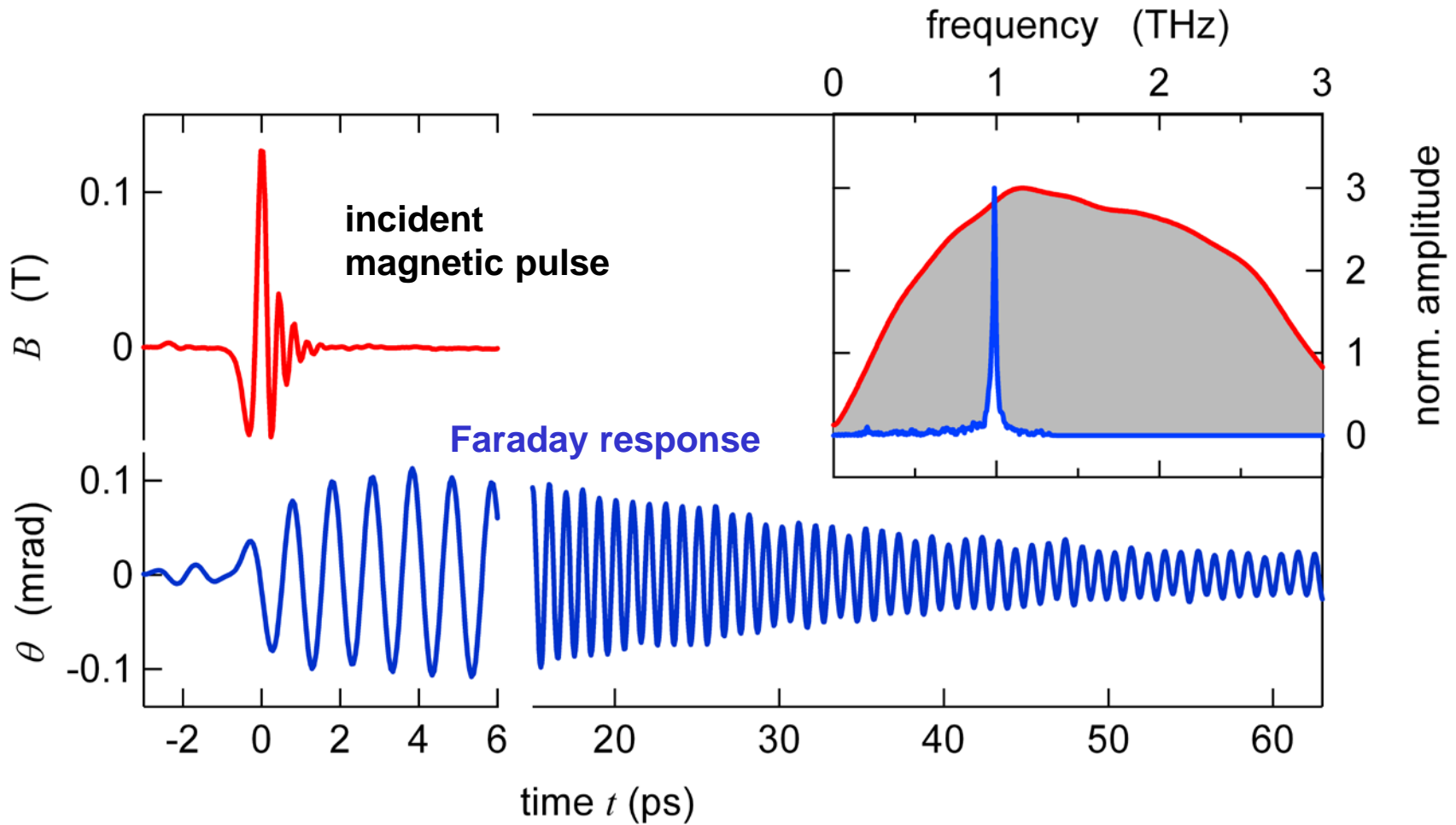


- adjacent (111) planes have opposite Ni²⁺ spins
- antiferromagnet with Neel temperature of 523K
- collective spin resonance ($q = 0$ magnon) at 1THz

NiO: A 'textbook' antiferromagnet

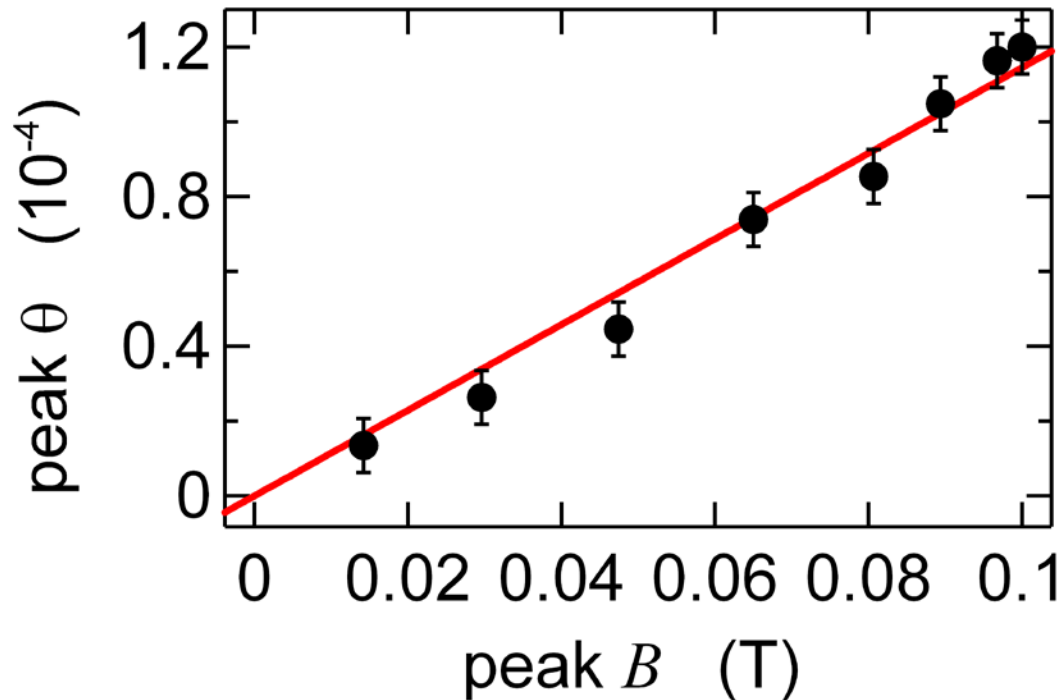


- adjacent (111) planes have opposite Ni²⁺ spins
- antiferromagnet with Neel temperature of 523K
- collective spin resonance ($q = 0$ magnon) at 1THz



oscillation at 1THz, decay time 40ps
 \Rightarrow signature of $q = 0$ magnon at 1THz

Spinwave driven by magnetic field



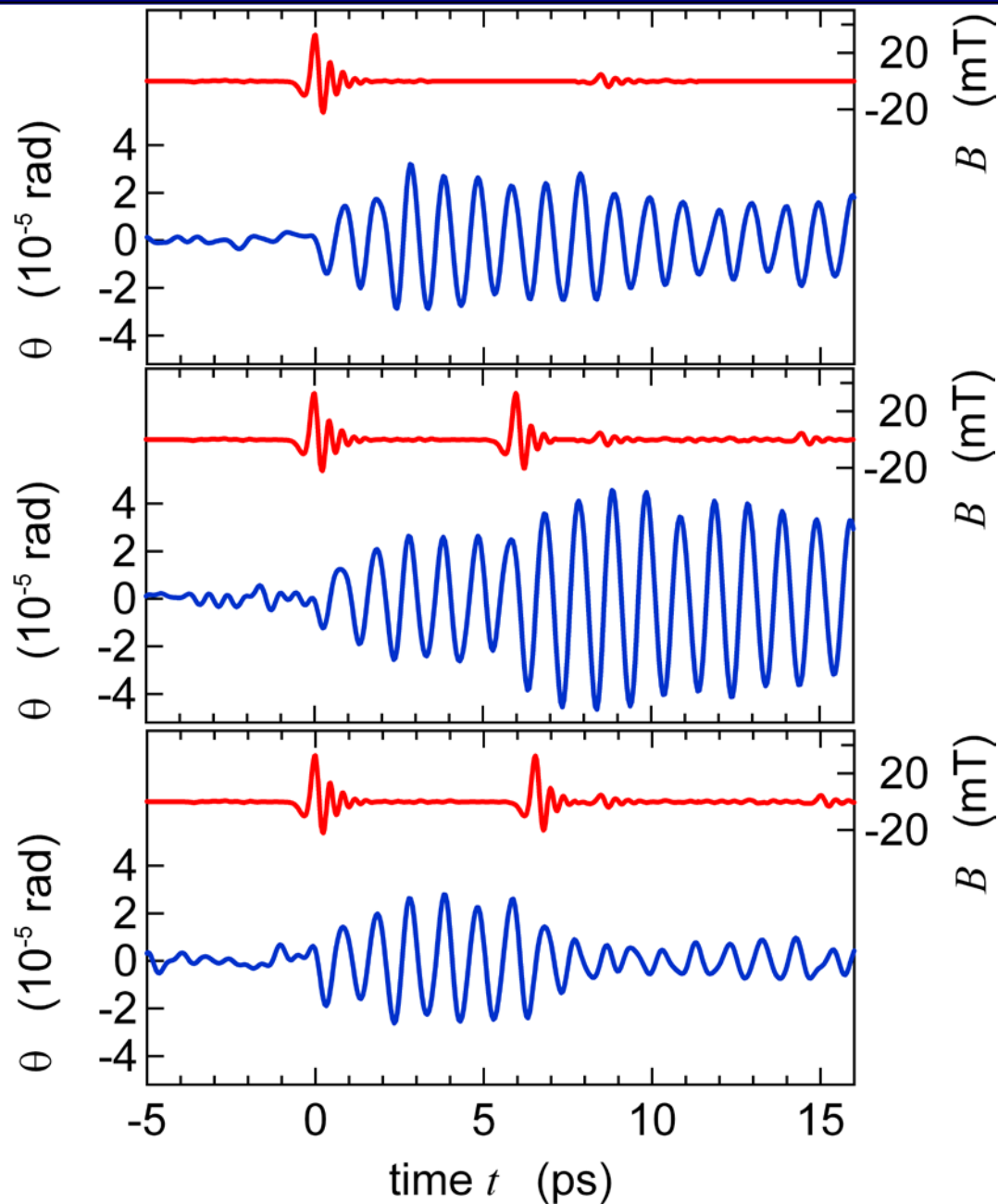
Observation: induced magnetization \propto driving field

\Rightarrow driving force is the magnetic (not electric) field !

\Rightarrow free carrier and lattice excitation negligible

(NiO is insulating & all optical phonons > 12 THz)

Coherent spin control with THz pulses

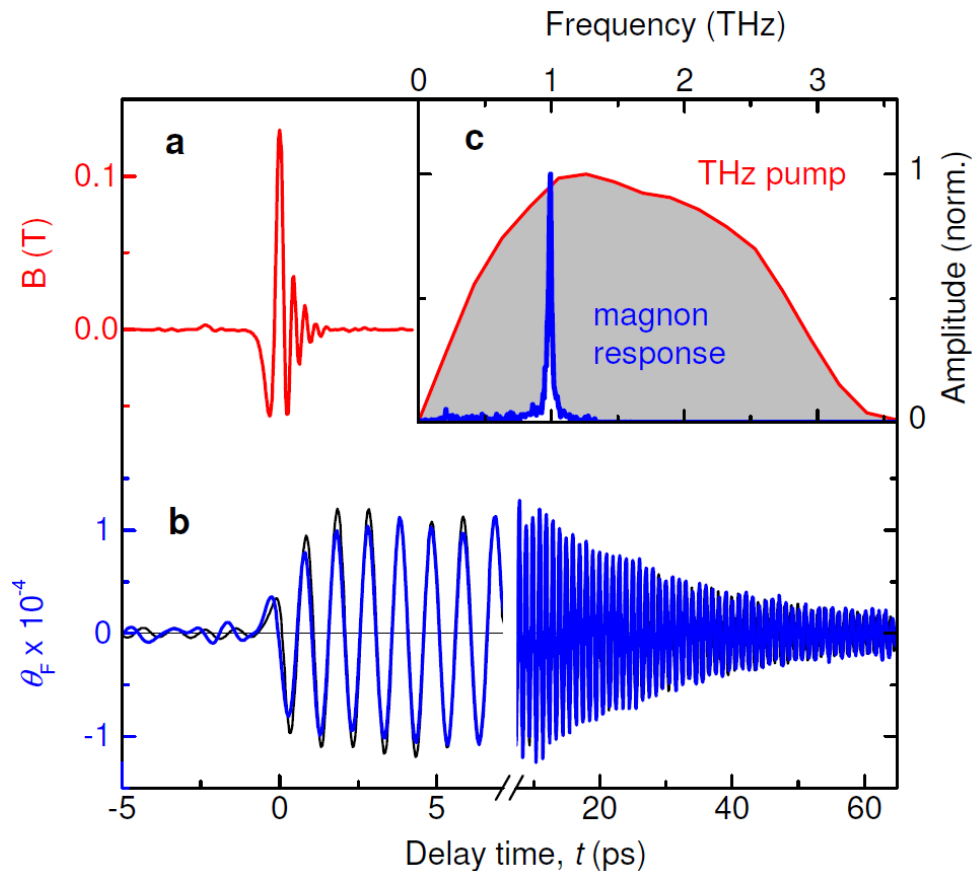


first THz pulse
excites magnon

second pulse
after **6ps**
amplifies magnon

second pulse
after **6.5ps**
switches
magnon off

Zeeman-torque driven coherent THz magnon in the time domain



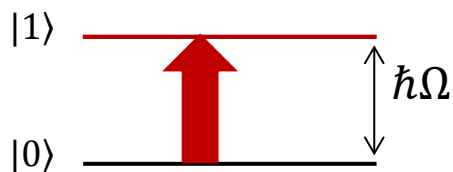
Benefits of coherent control with THz magnetic fields:

- does not require spin-orbit coupling
- no parasitic two-photon absorption
- fields up-scalable without sample destruction

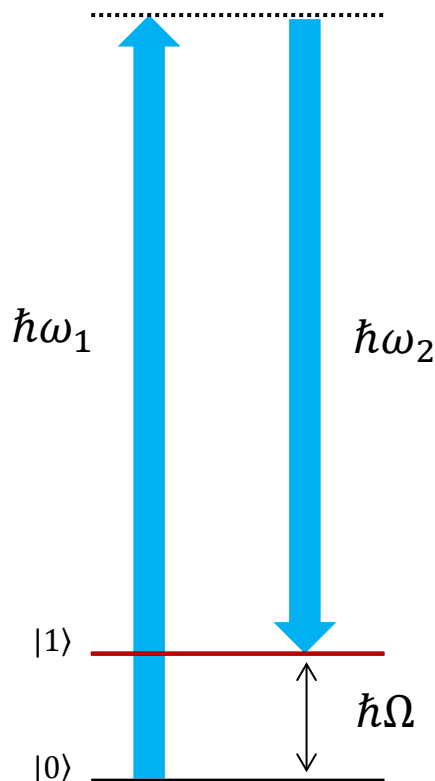
Excitation of IR or Raman active phonon modes

IR active

Raman active

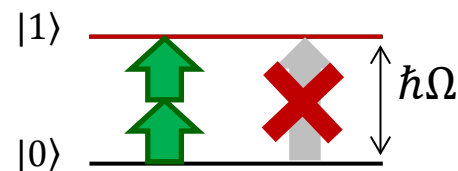


resonant
one photon
IR excitation



stimulated
difference frequency
Raman excitation
(SRS)

Coherent lattice
excitation of
Raman mode via
non-resonant
two-photon
absorption ?



2 photon
sum frequency
Raman excitation

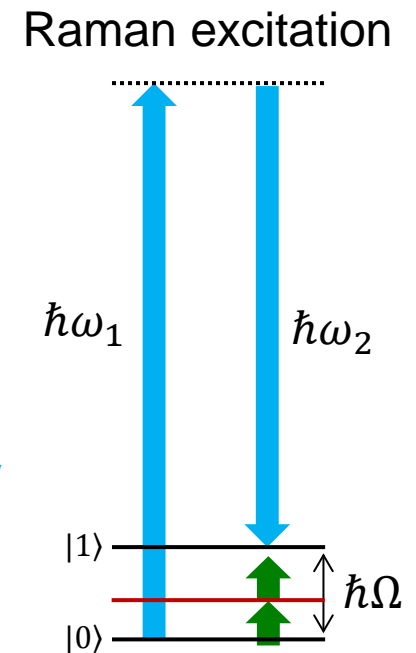
Equation of motion

$$\ddot{Q} = \underbrace{-\frac{\partial V}{\partial Q}}_{\text{e.g. harmonic oscillator}} + \underbrace{E \frac{\partial P(Q, 0)}{\partial Q}}_{\text{direct}} + \underbrace{E^2 \frac{\partial \chi(Q)}{\partial Q}}_{\text{Raman-type}} \text{ Raman-tensor}$$

= 0 (Raman mode, not IR active)

$$E(t) = \Re [A_1 e^{-i\omega_1 t} + A_2 e^{-i\omega_2 t}]$$

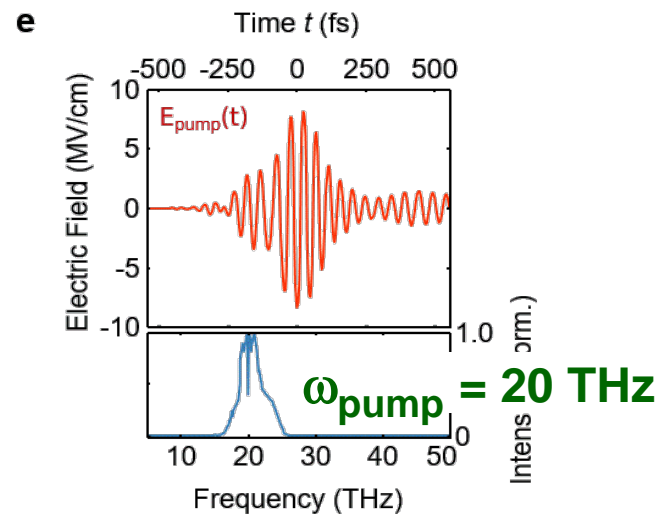
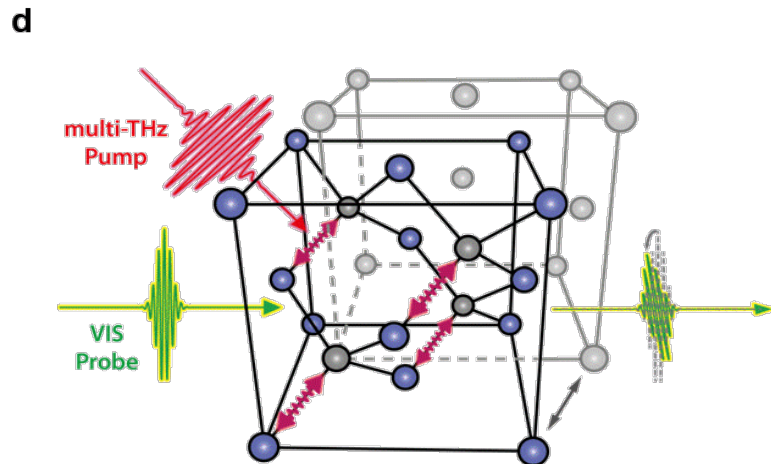
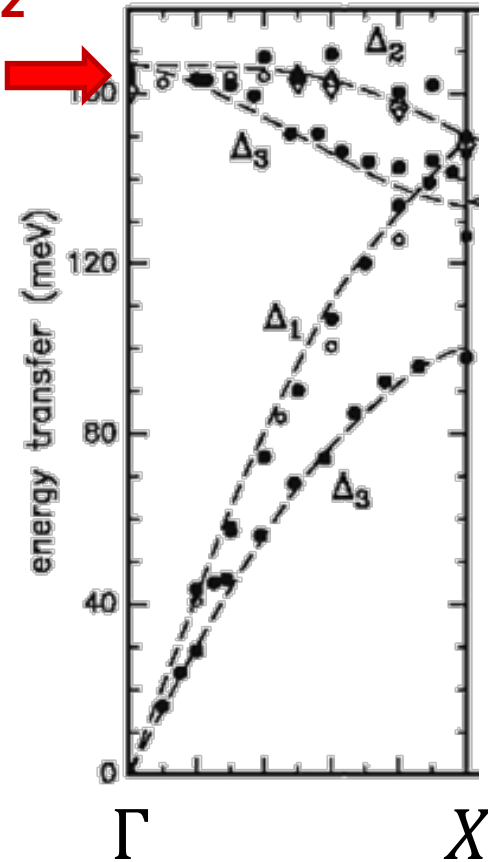
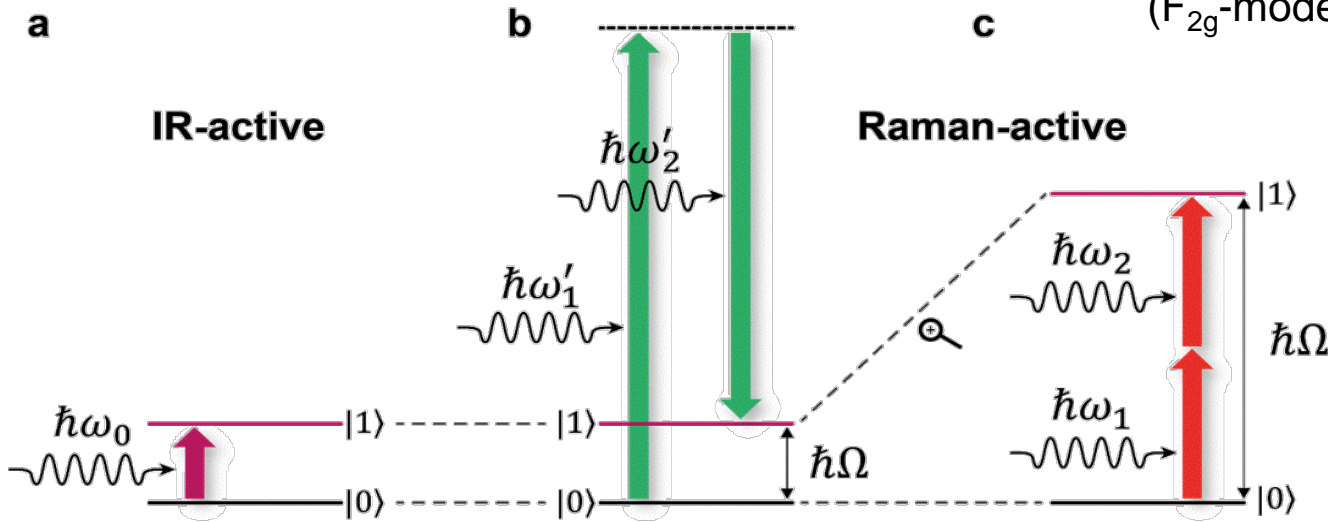
$$(E(t))^2 \sim \begin{cases} +e^{-i(\omega_1 - \omega_2)t} & \text{non resonant difference frequency} \\ +e^{-i(\omega_1 + \omega_2)t} & \text{non resonant sum frequency} \\ +c.c. \\ +\dots \end{cases}$$



THz-pumping of F_{2g} -mode in Diamond

Non-resonant THz pumping of diamond

$\Omega = 40$ THz

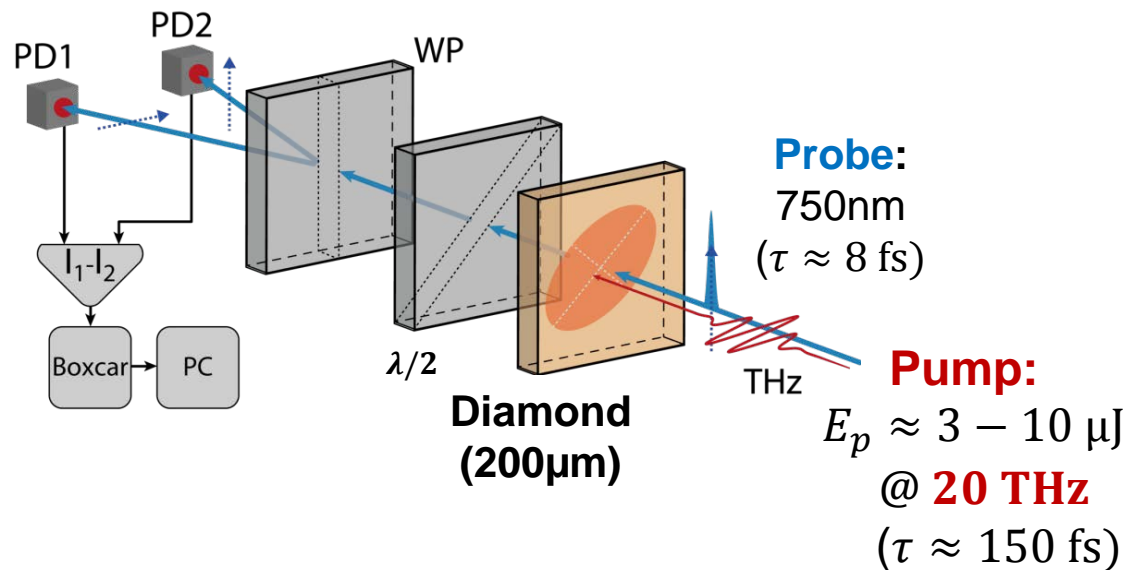
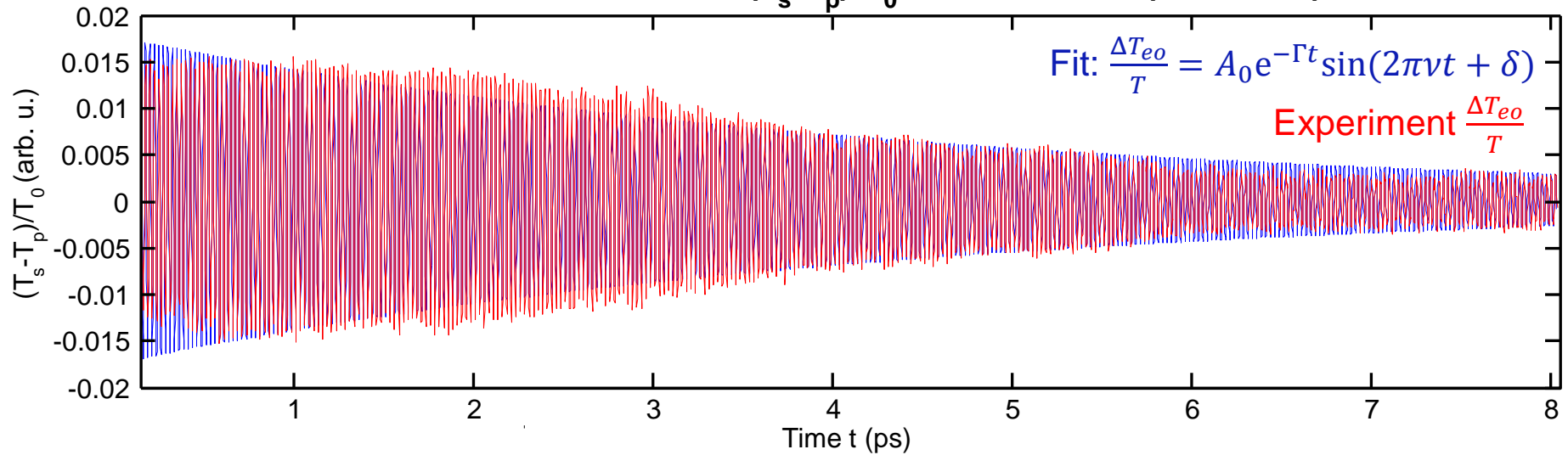


C-C stretch vibration @ 40 THz

Phonon band structure of diamond

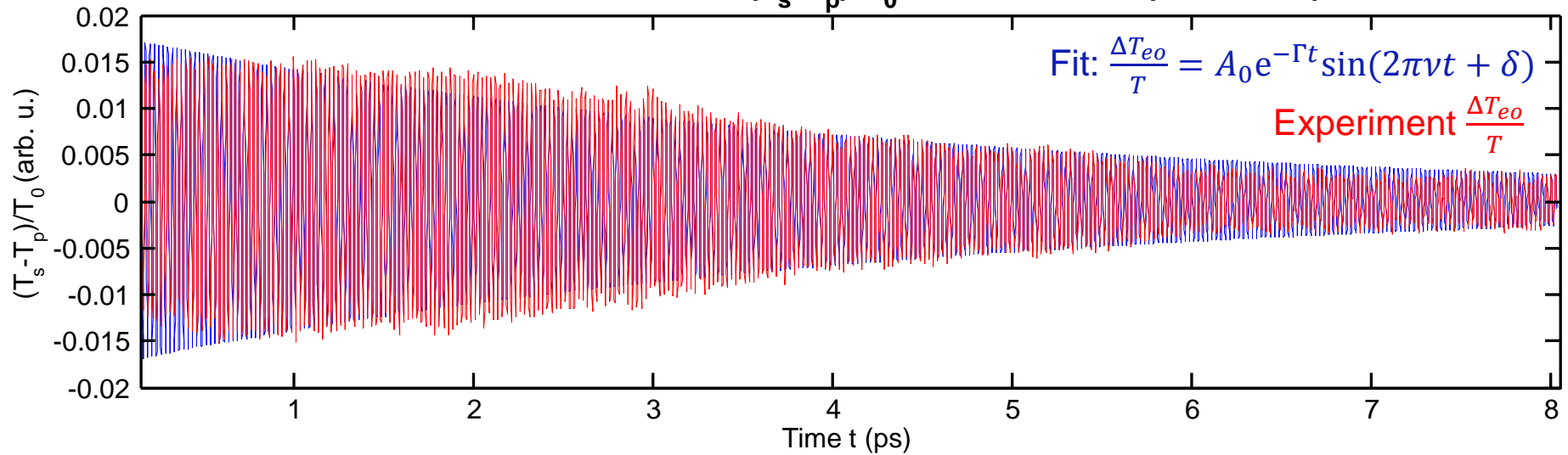
THz-pumping of F_{2g} -mode in Diamond

Polarization rotation $(T_s - T_p)/T_0$ transmission ($\lambda=750\text{nm}$)

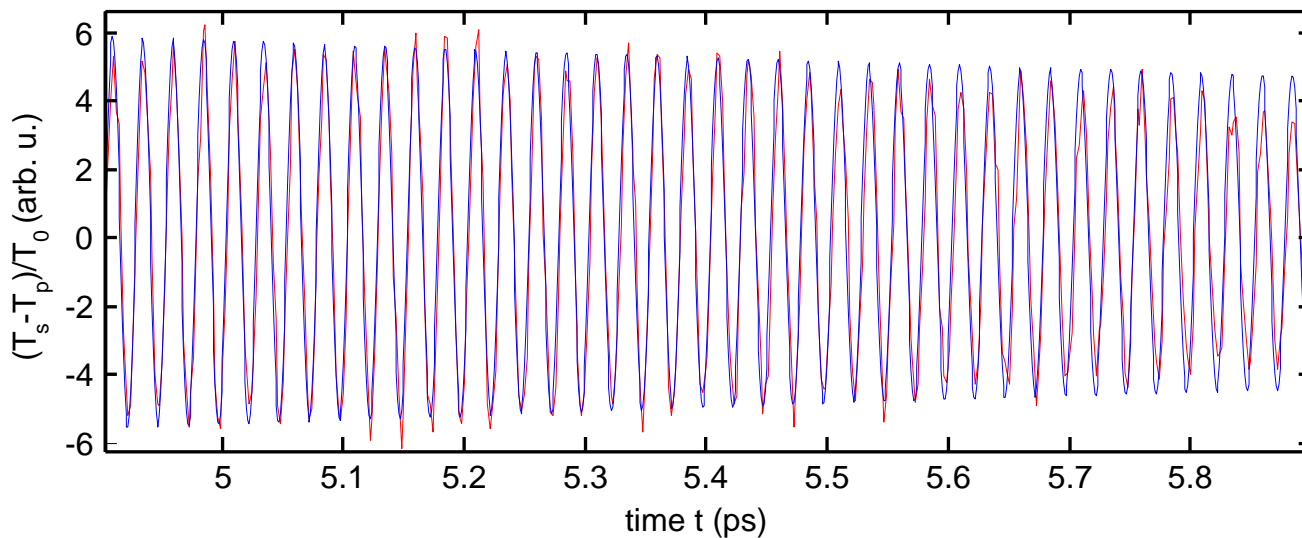


THz-pumping of F_{2g} -mode in Diamond

Polarization rotation $(T_s - T_p)/T_0$ transmission ($\lambda=750\text{nm}$)



detail



Fit results:

$$\Gamma = 0.229 \text{ ps}^{-1}$$

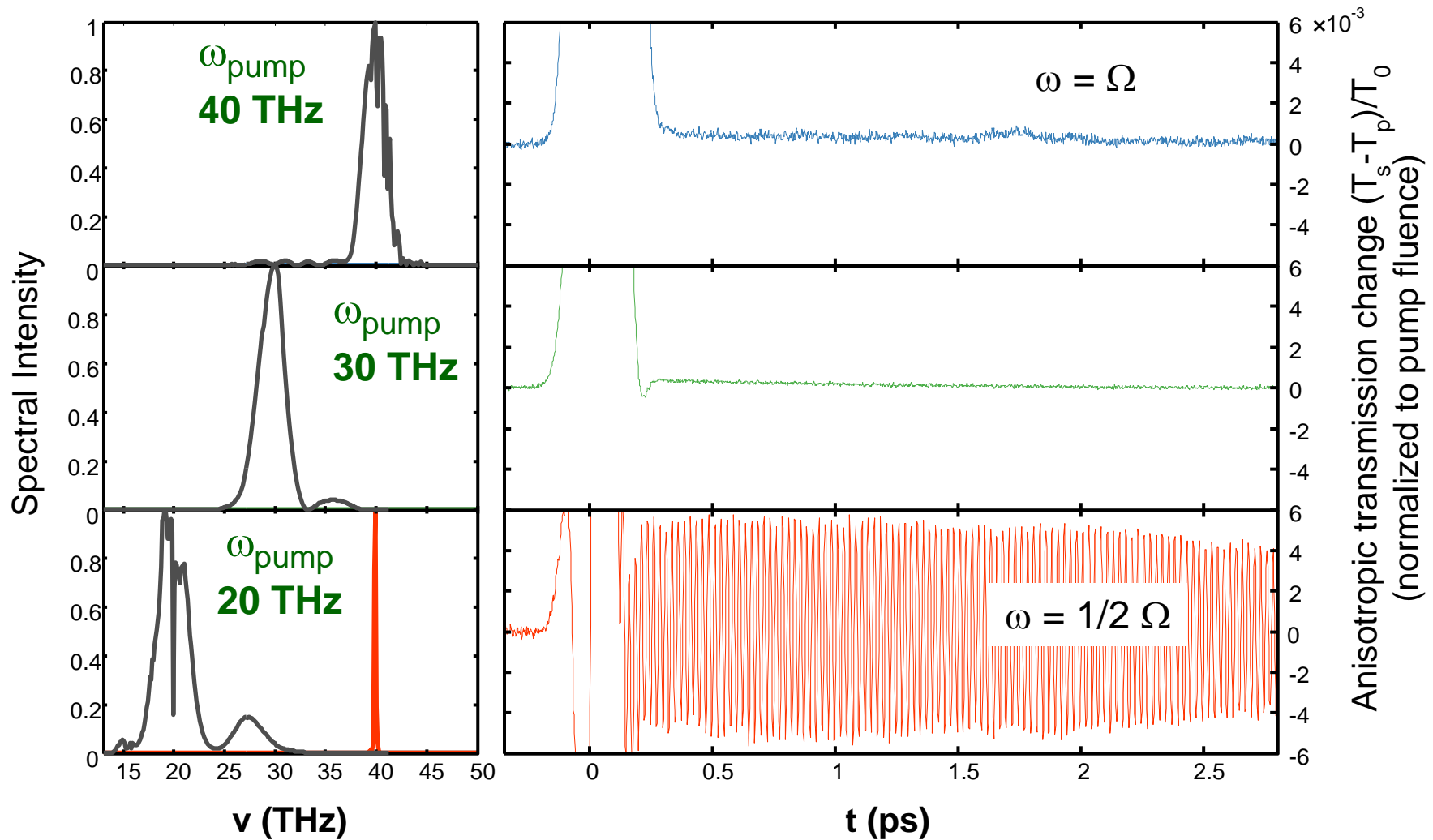
$$\nu = 39.95 \text{ THz}$$

consistent with
Ishioka et al, APL 2006

$$\Gamma = 0.145 \text{ ps}^{-1}$$

$$\nu = 39.84 \text{ THz}$$

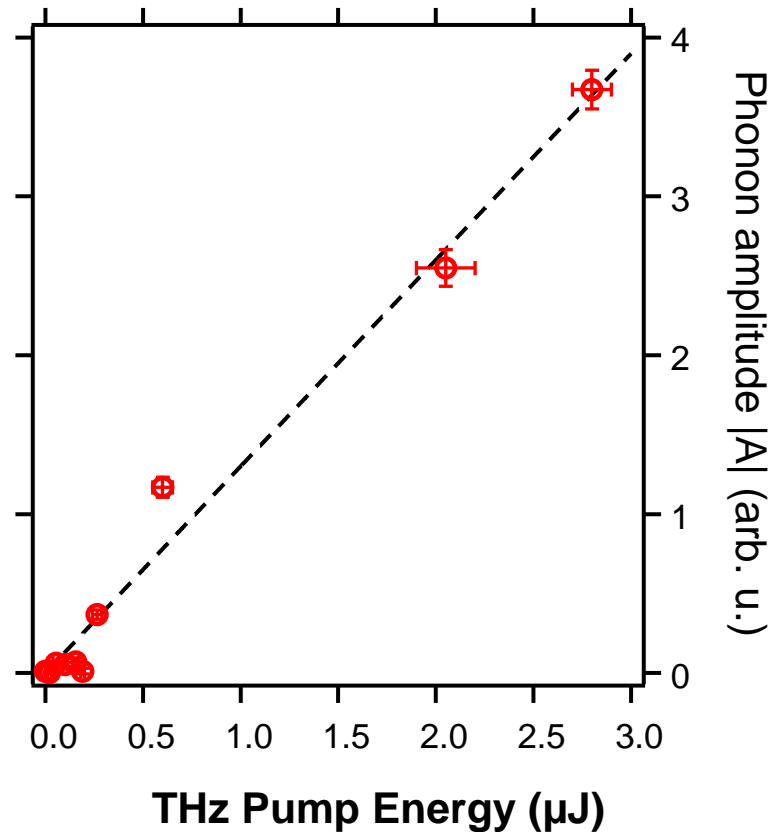
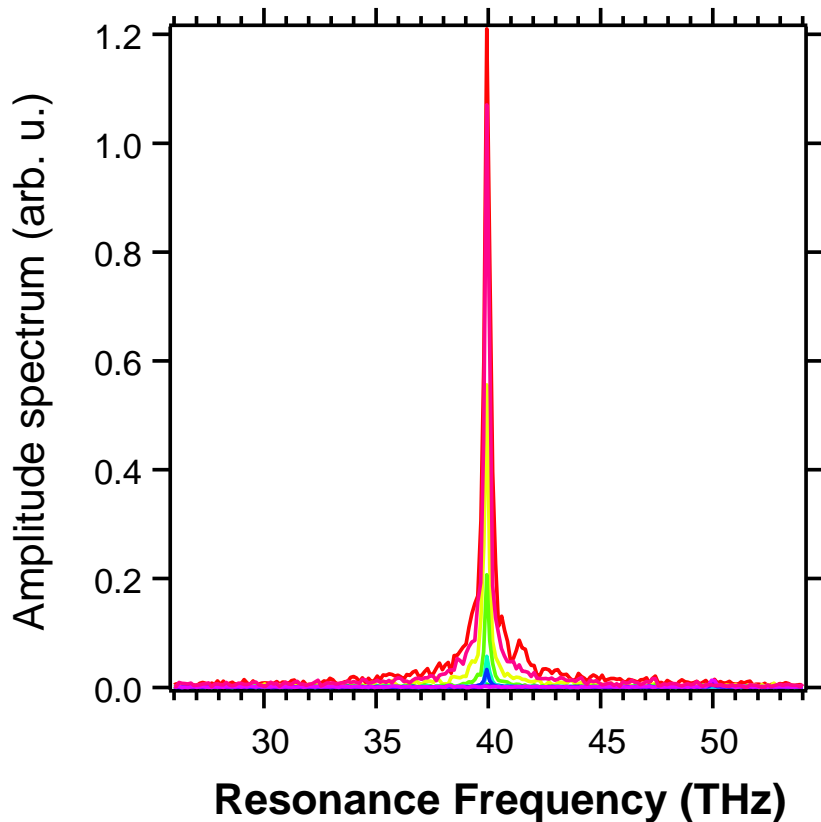
Dependence on excitation frequency



Coherent excitation of the F_{2g} phonon at **half-resonance** frequency $\omega = 1/2\Omega$

Is this a sum frequency Raman process ?

check fluence dependence



- ✓ Central frequency independent
- ✓ Damping constant independent

- ✓ **Phonon amplitude $\sim I \sim E^2$**
- ✓ Raman tensor symmetry

Demonstration of sum frequency Raman excitation

Benefits of sum frequency Raman excitation

Sum frequency Raman excitation allows to actively **control the phase of coherent phonons** by setting a pump pulse with dedicated **carrier envelope phase (CEP)** !

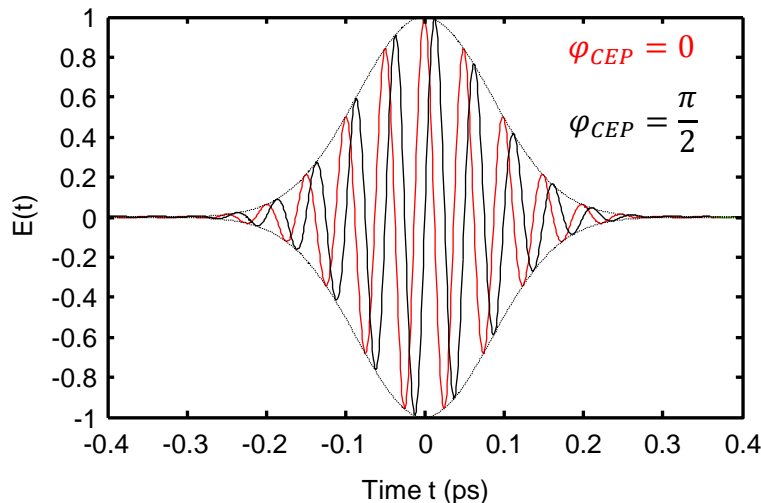
$$\longrightarrow E(t) = A_1 e^{-i\omega_1 t + \varphi_{CEP}} + A_2 e^{-i\omega_2 t + \varphi_{CEP}} + c. c.$$

difference frequency
Raman excitation

$$[E(t)]^2 \sim e^{-i(\omega_1 - \omega_2)t} + c. c.$$

sum frequency
Raman excitation

$$[E(t)]^2 \sim e^{-i(\omega_1 + \omega_2)t + 2\varphi_{CEP}} + c. c.$$



THz generation scheme:

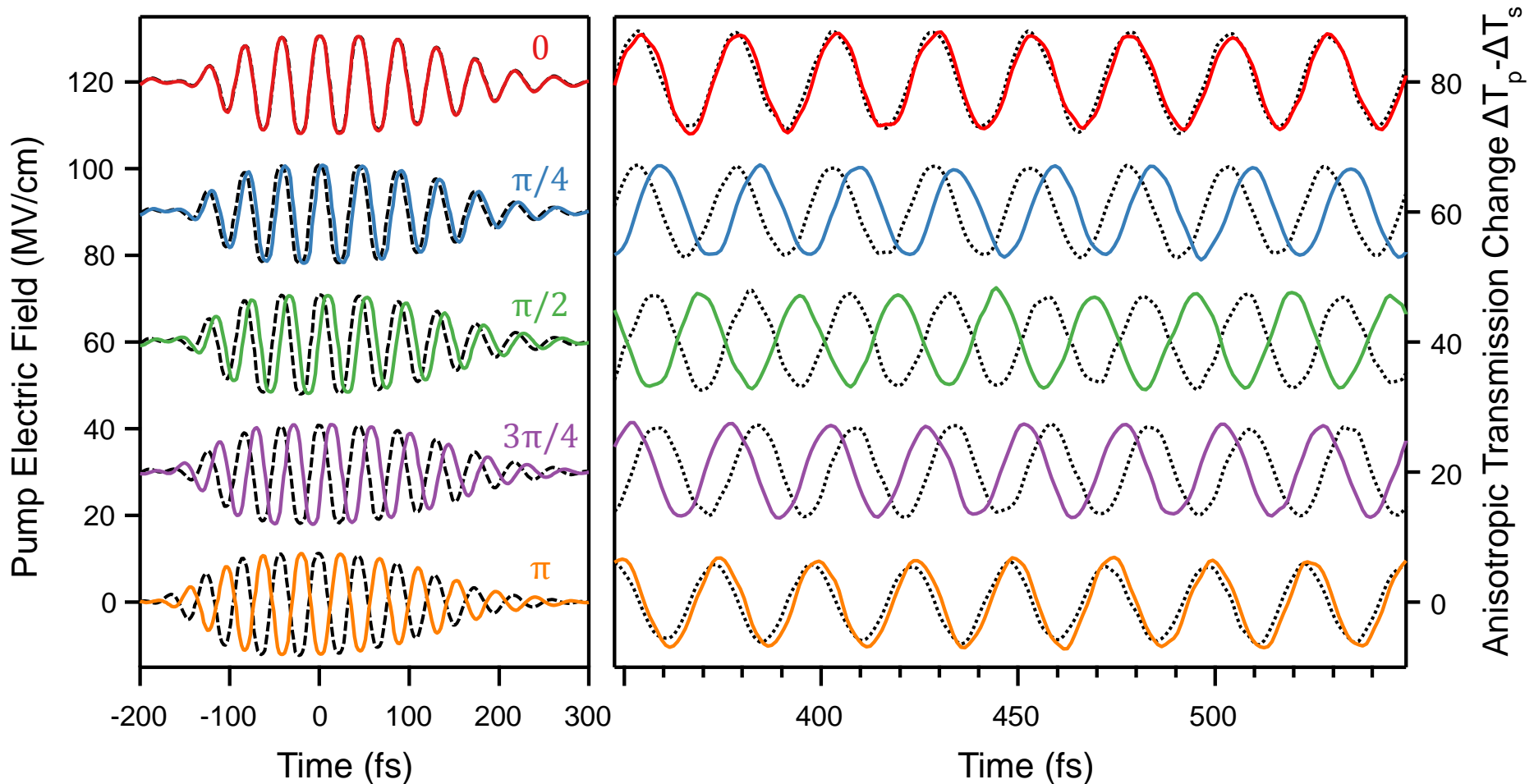
difference-frequency mixing in GaSe
of 2 phase-correlated infrared pulses

\longrightarrow **CEP phase controlled** by delay

Phase Control via the THz-CEP

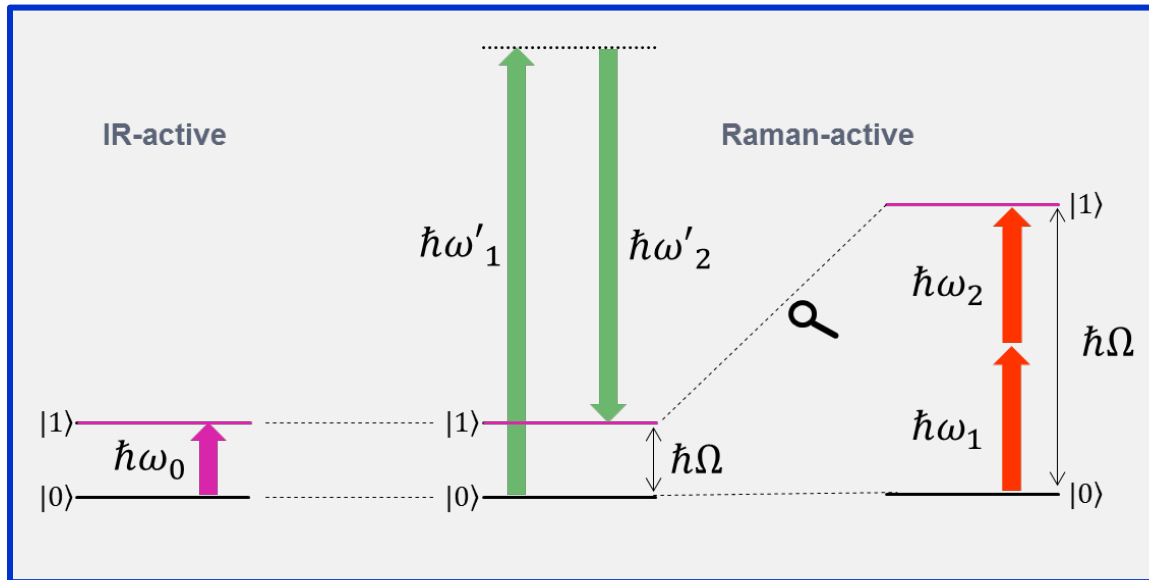
Pump Electric field CEP

Coherent phonon response



➔ as expected: $\varphi_{\text{phonon}} = 2 \cdot \phi_{\text{CEP}}$

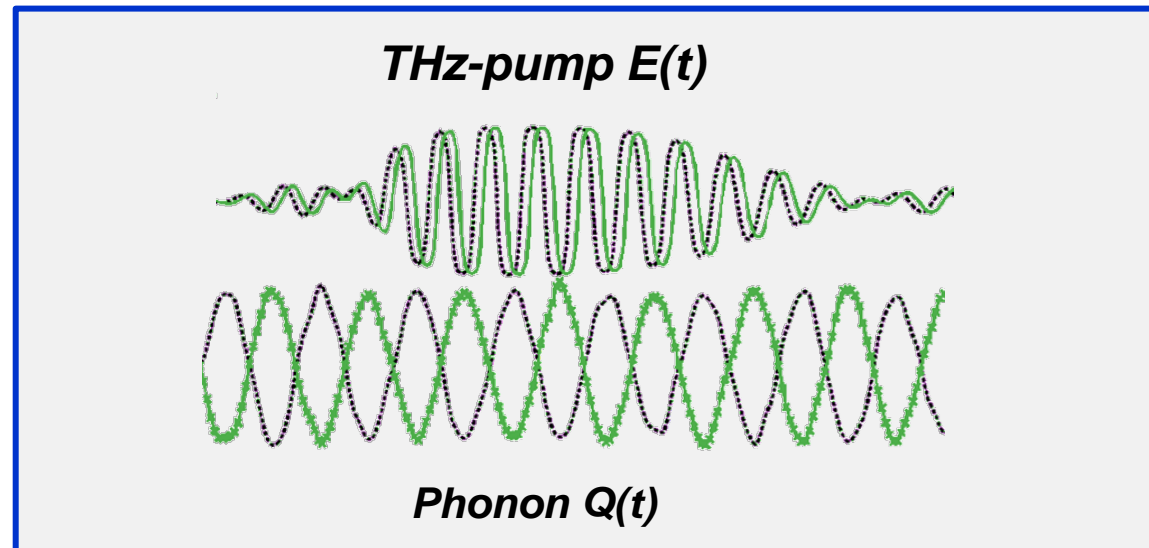
Light field CEP is imprinted on the coherent phonon phase!



New mechanism for coherent phonon excitation:

sum frequency Raman excitation

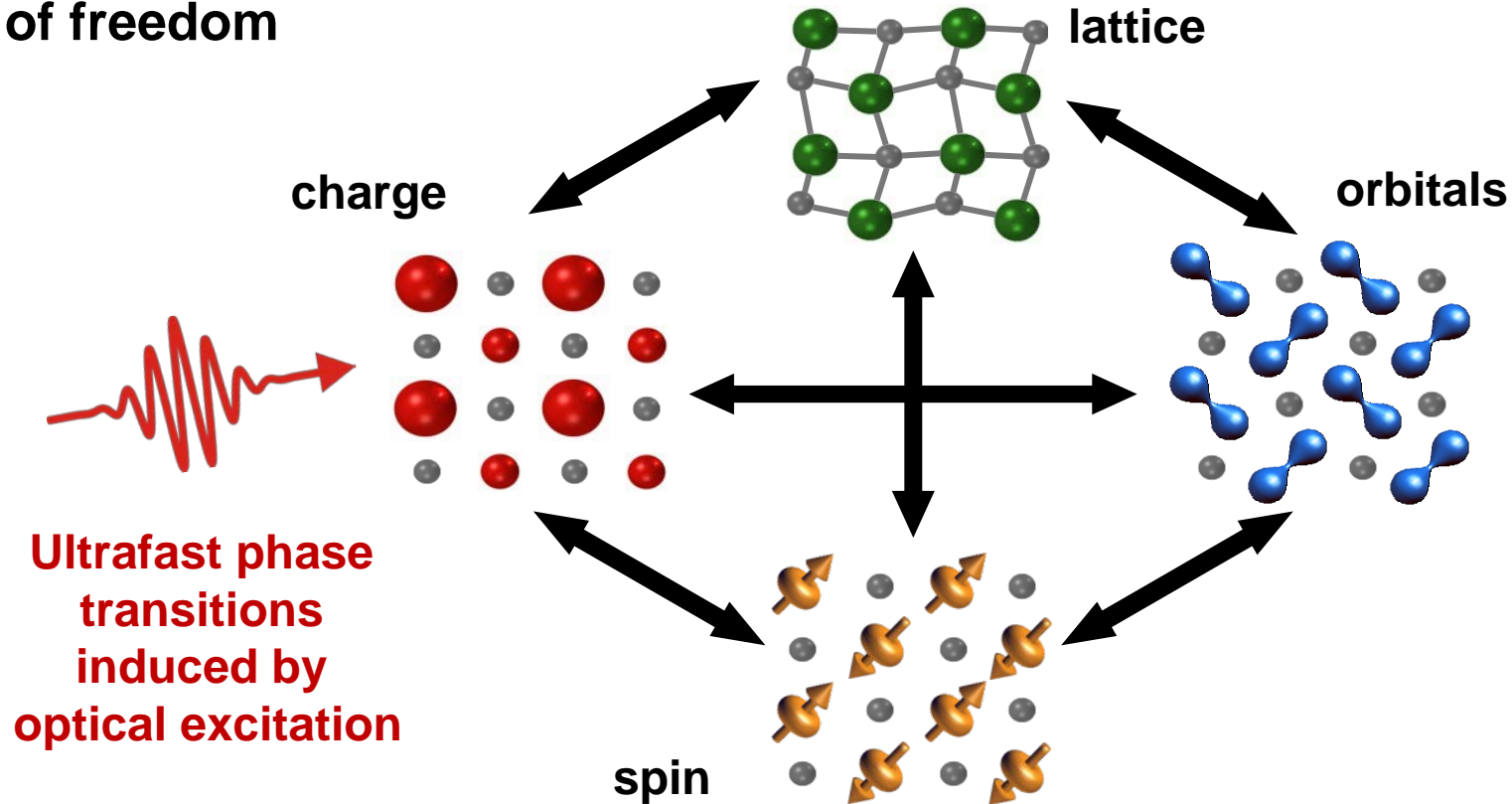
prevents parasitic electronic excitations



Coherent control of the **phonon phase** via control of THz-pump CEP

Motivation: Elementary interactions in solids

Coupling between the various degrees of freedom



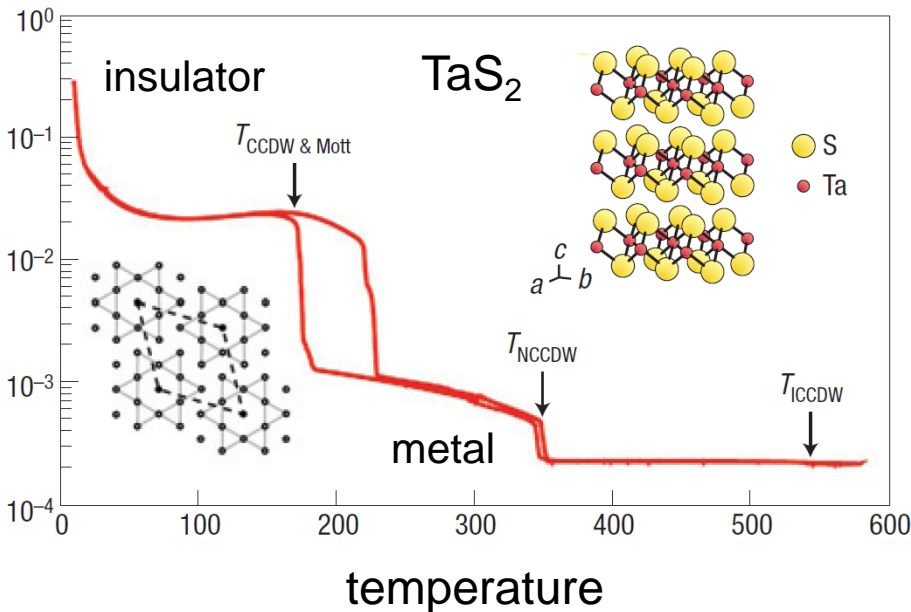
Goal: Mechanistic understanding of the coupling and energy flow between the subsystems governing ultrafast phenomena

Photoinduced insulator-to-metal
transition in tri-tellurides ($R\text{Te}_3$)

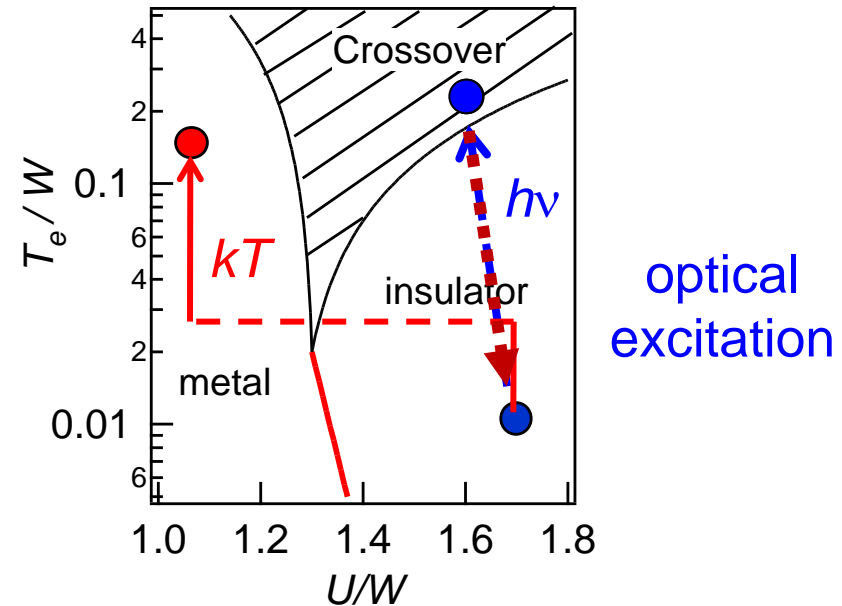
Coherent amplitude mode excitation
probed by
time-resolved photoemission (ARPES)

Phase transitions and ultrafast dynamics

- ▶ Phase transitions in solids (near equilibrium)



- ▶ Ultrafast photoexcitation (non-equilibrium)



- ▶ What can be learned from bringing the system out of equilibrium?

➡ Timescale to induce a transition to a non-equilibrium state

➡ Spectroscopy of such excited states and 'new' phases

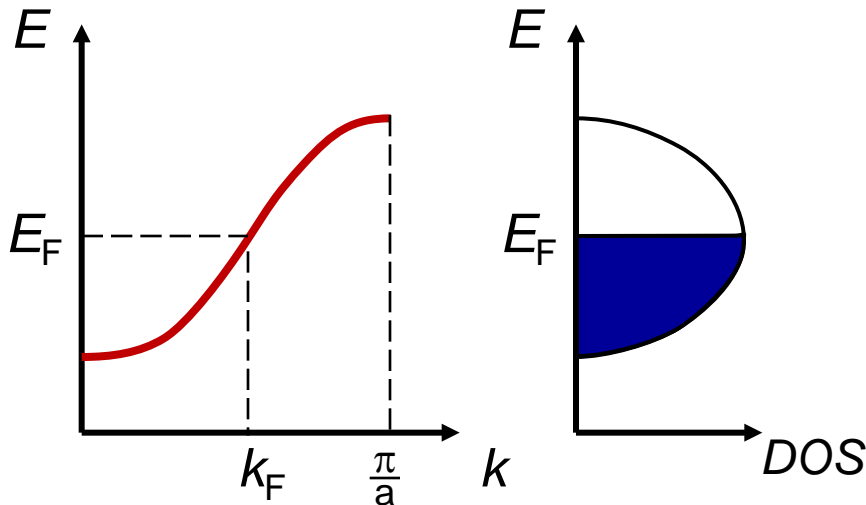
➡ Timescale for the return to equilibrium
Sipos et al., Nature Mater. 7, 969 (2008)

Electronic band structure of solids

What is the origin of metallic, semiconducting and insulating behaviour?

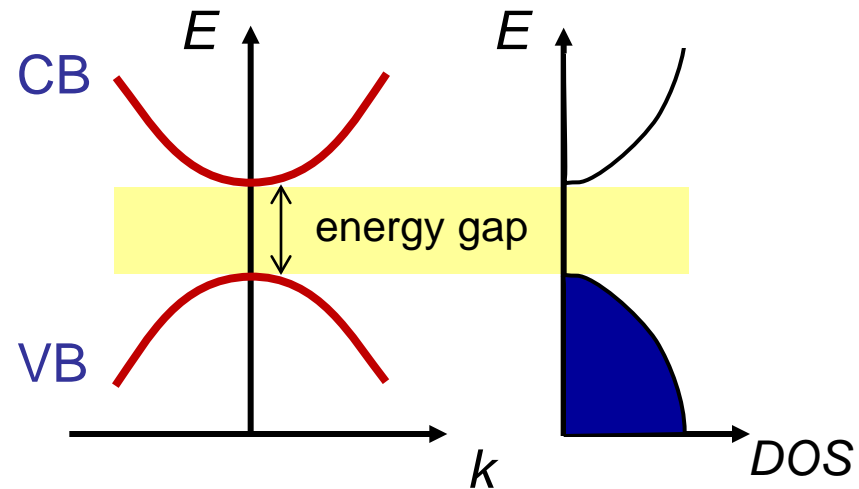
- ▶ Use single-particle band theory (*i.e.* neglect e-e correlations)

simple metal



- ▶ half filled band \Leftrightarrow metal

insulator, semiconductor

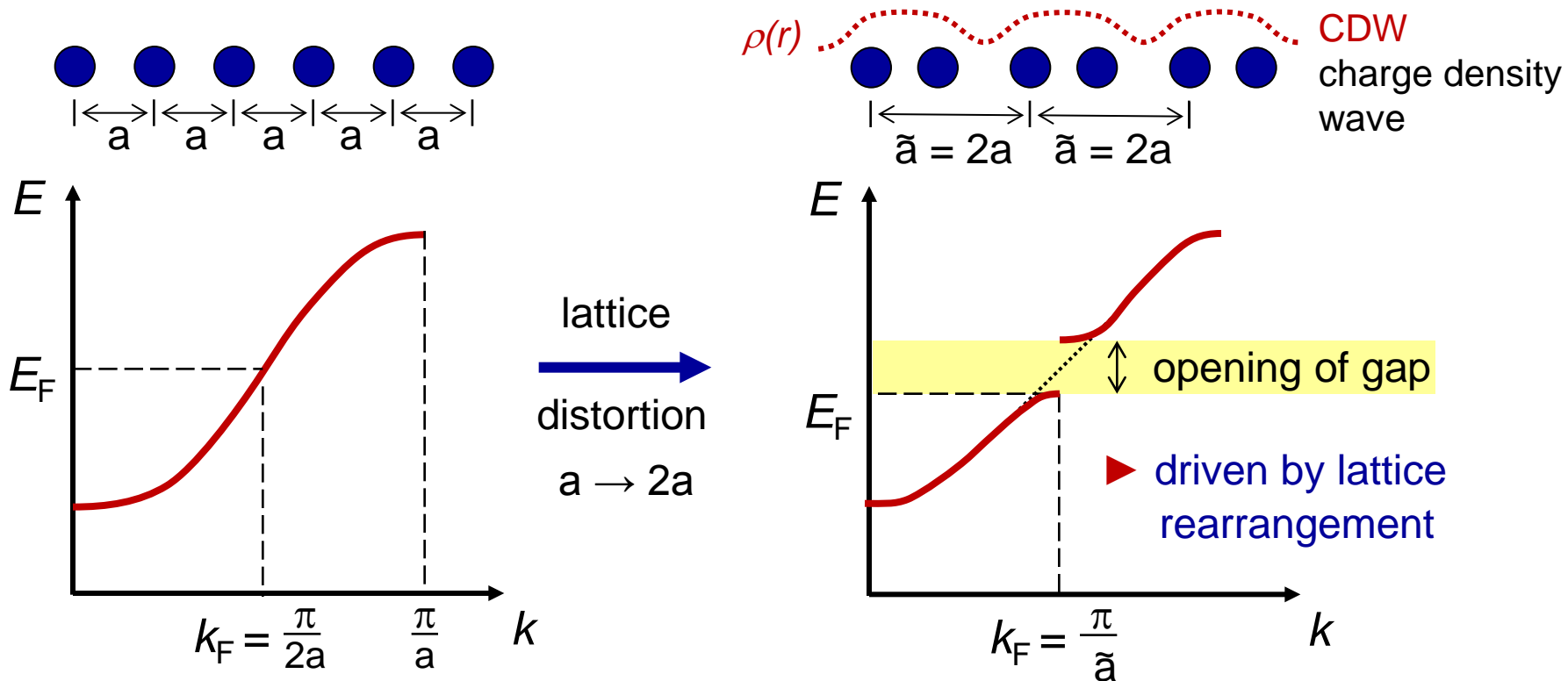


- ▶ filled valence band \Leftrightarrow insulator
or semiconductor

Charge density wave formation

Are materials with a half filled valence band always metals?

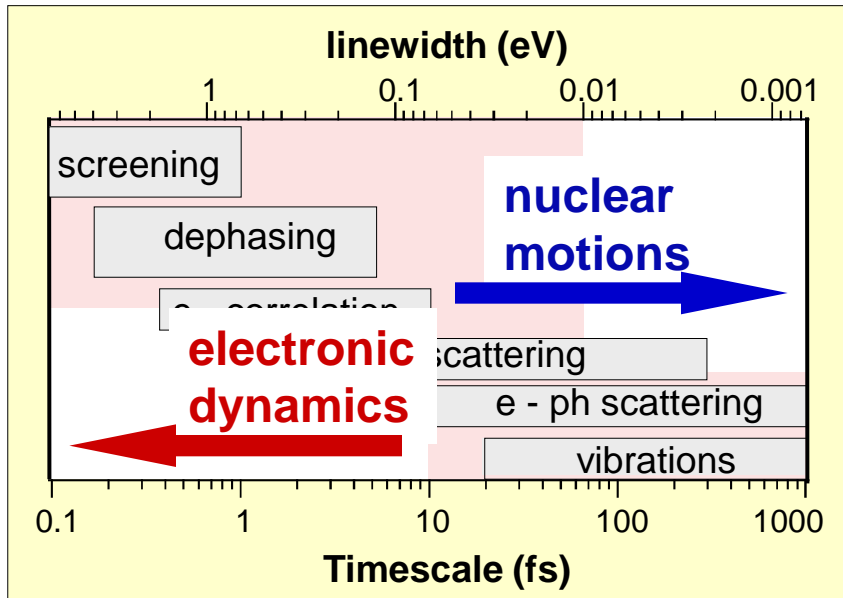
- ▶ One-dimensional metallic system with a half filled band can be unstable against lattice distortion → **Peierls instability**



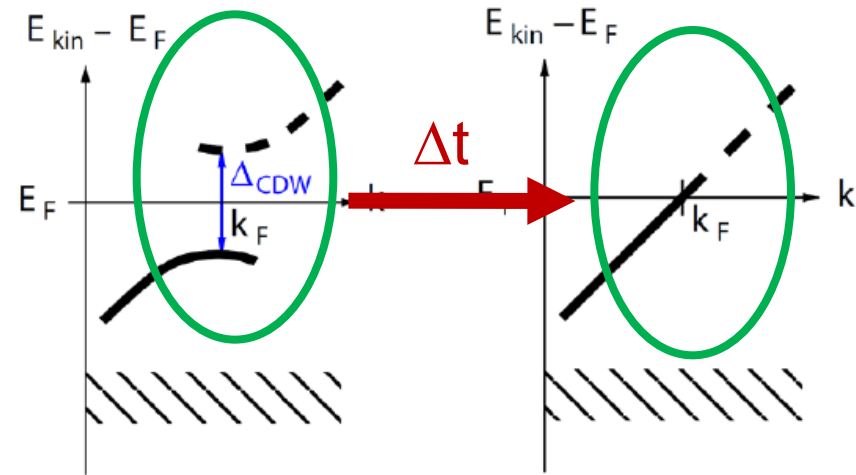
- ▶ Note: wave vector $2k_F = \frac{\pi}{a}$ fulfills Bragg reflection condition

Ultrafast photoinduced phase transitions

- ▶ What can be learned by bringing the system out of equilibrium?



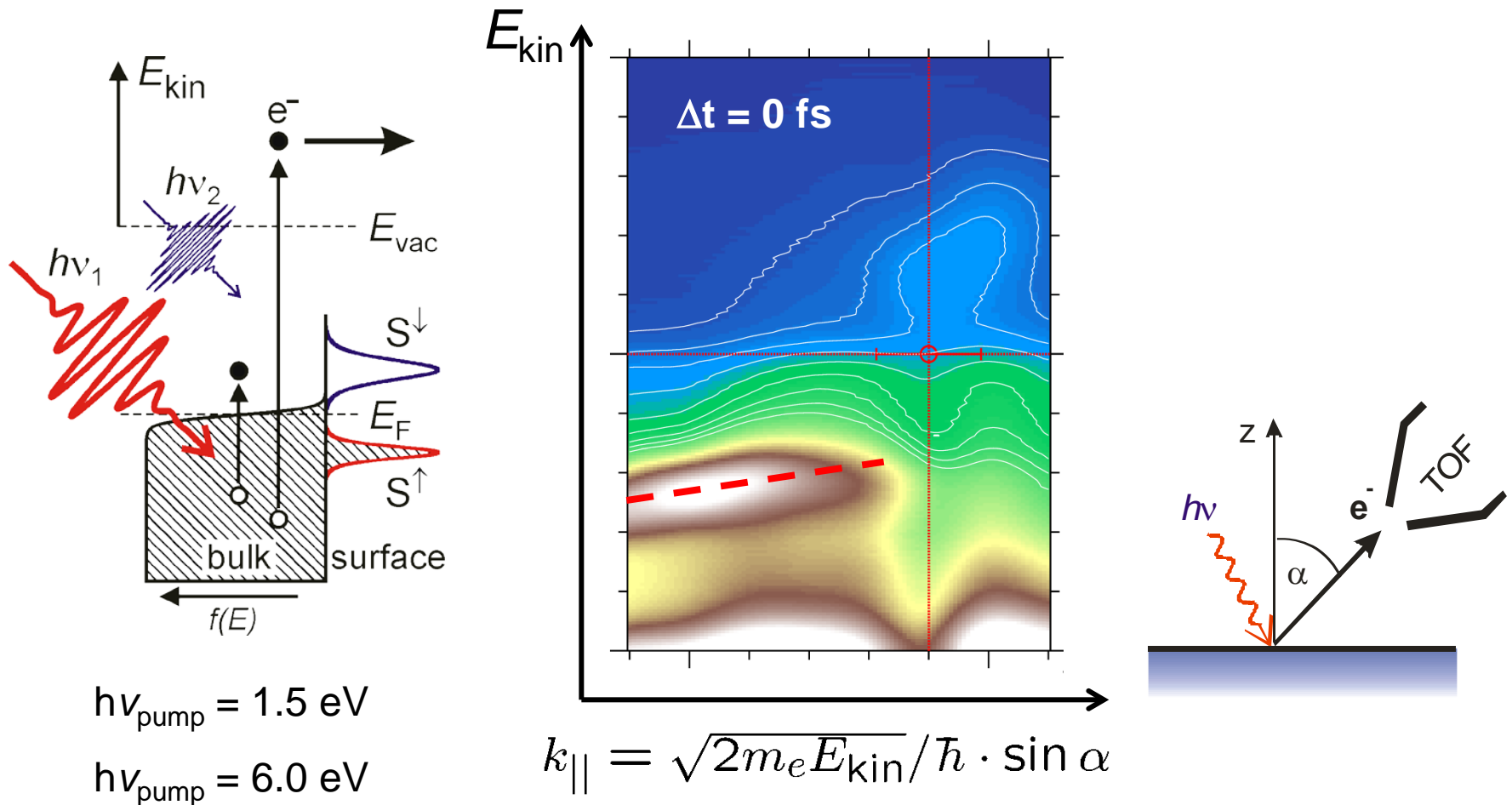
Example: Metal-Insulator transition



- ▶ Exploit separation of timescales between different processes:
 - ▶ Timescale to induce the transition to a different phase
 - ▶ Probing the dynamics of the order parameter
(How fast is the gap closing? Is there coherent dynamics)

Transient electronic structure probed by trARPES

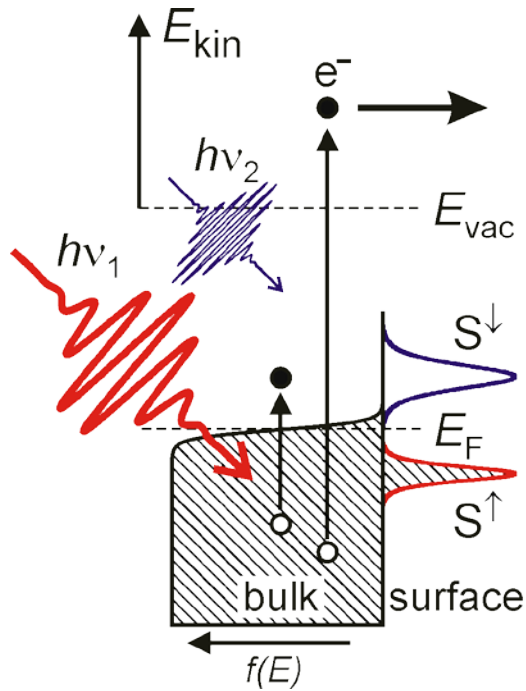
- ▶ Adding time-resolution to **angle-resolved photoemission (ARPES)** provides direct access to the transient electronic structure of photoexcited solids



Transient electronic structure probed by trARPES

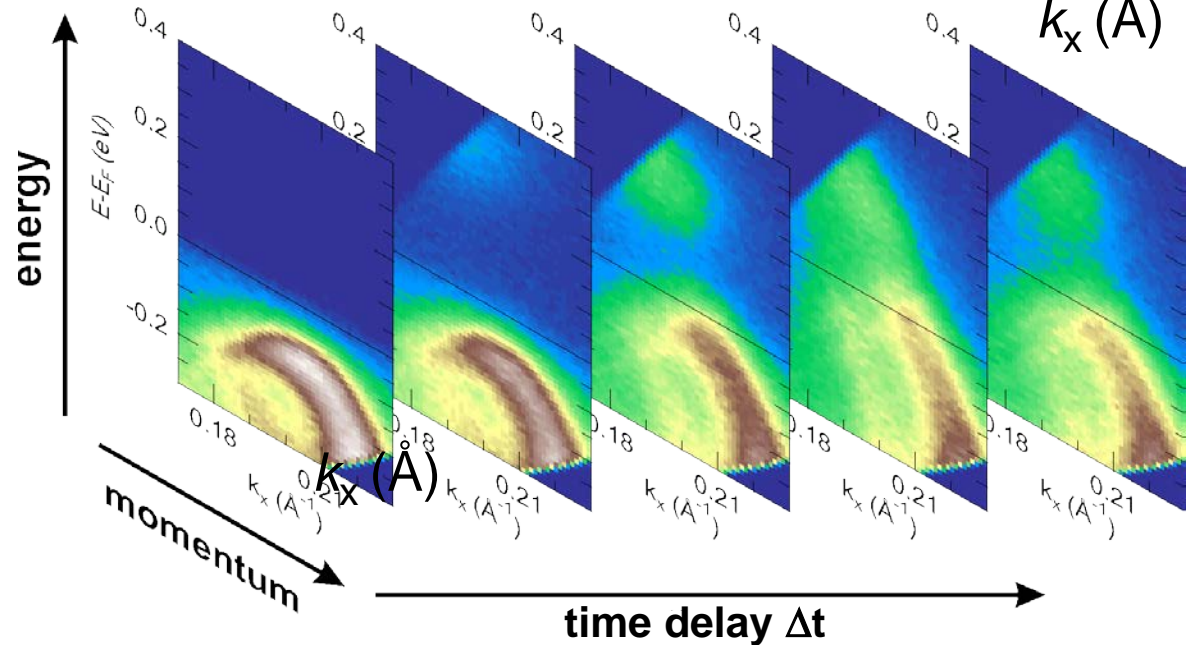
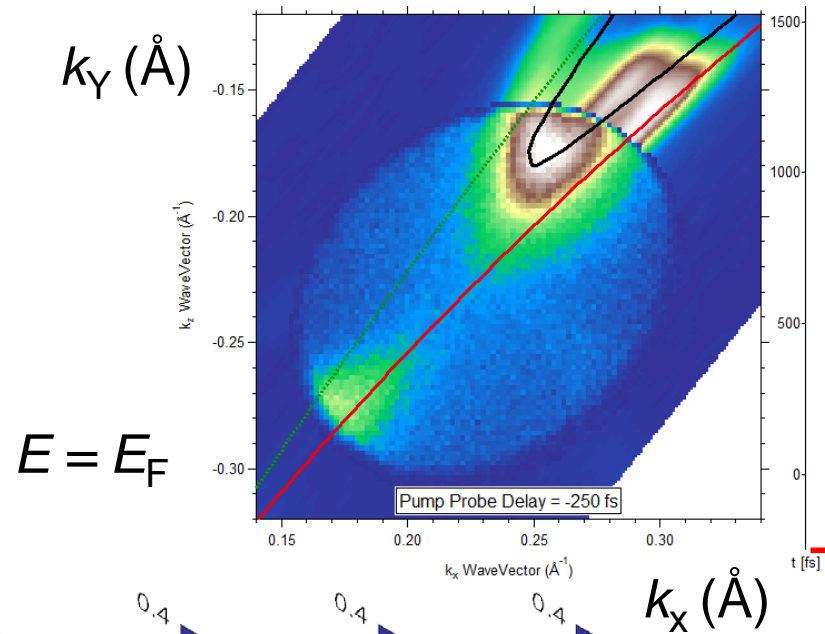
- ▶ Recording movies of photinduced changes of electronic band structure

$$E(k_x, k_y, \Delta t)$$



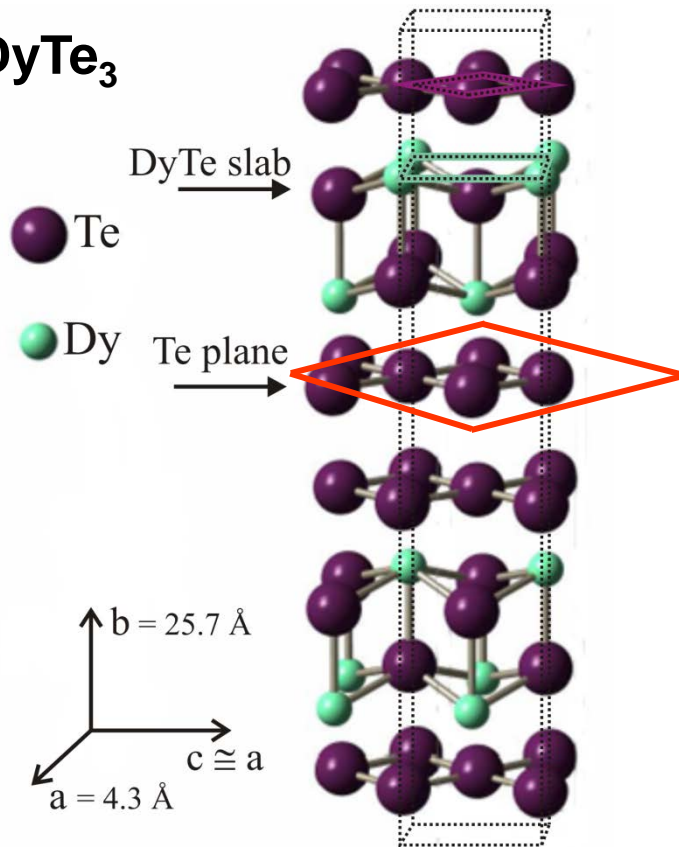
$$h\nu_{\text{pump}} = 1.5 \text{ eV}$$

$$h\nu_{\text{probe}} = 6.0 \text{ eV}$$



Tri-Tellurides – a model CDW system

DyTe₃

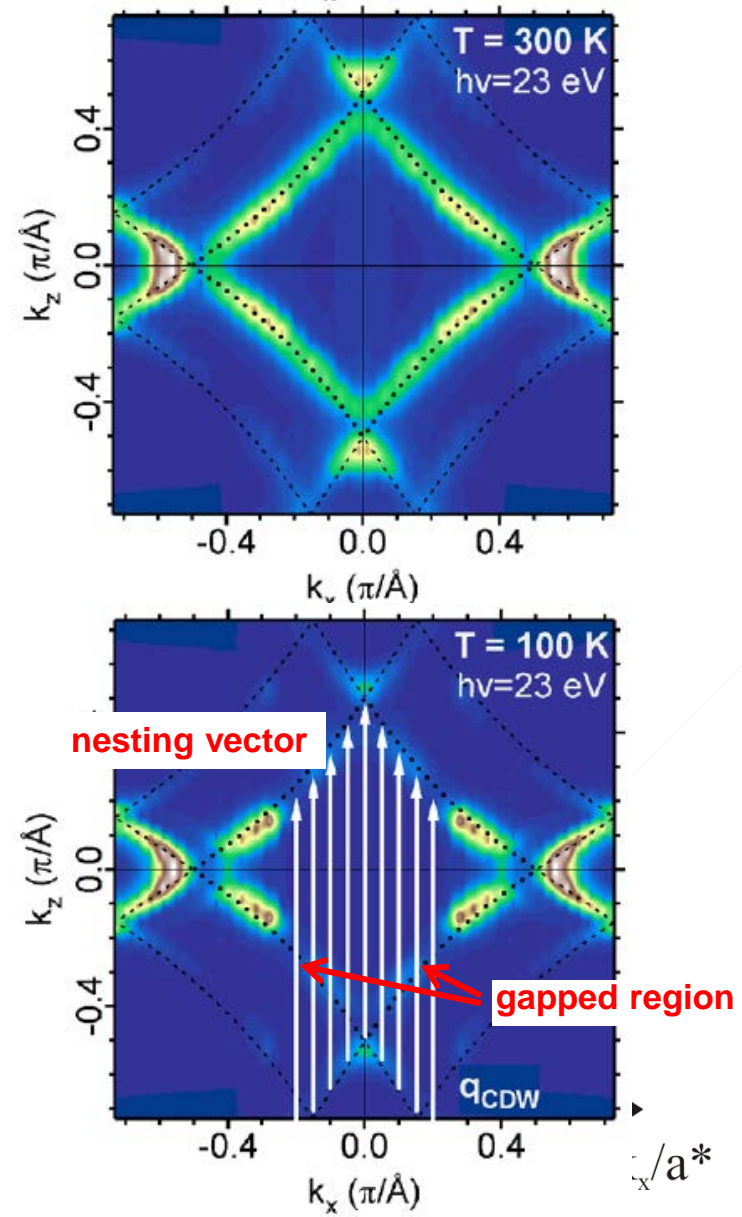


Tight-binding model: Te 5p orbitals coupled by t_{\parallel} and t_{\perp}

Diamond shaped Fermi surface

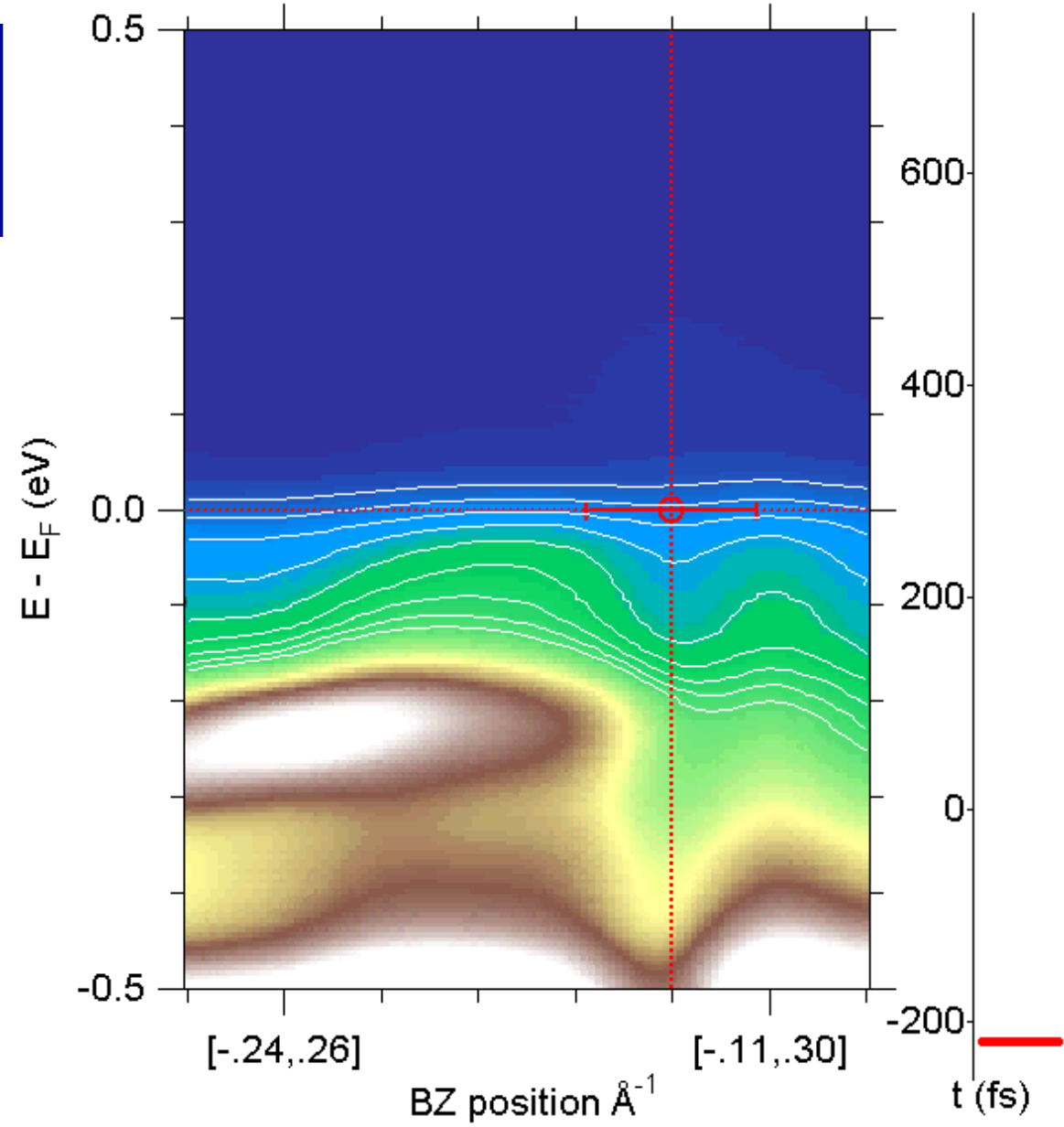
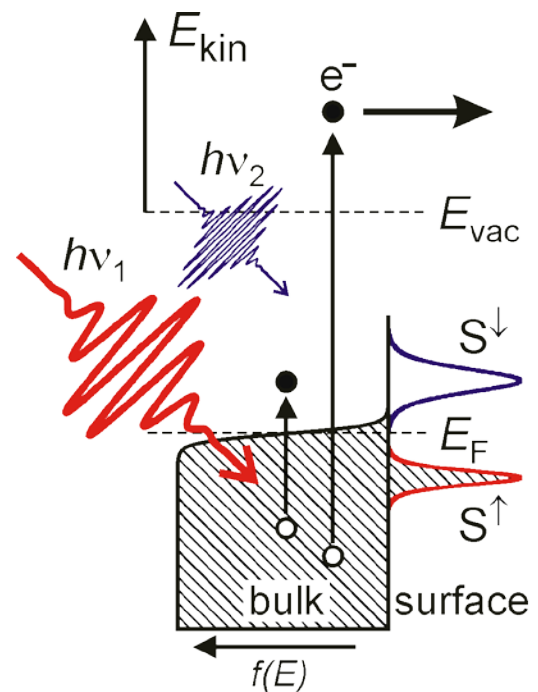
Curvature of bands \propto ratio t_{\perp}/t_{\parallel}

Fermi surface of TbTe₃



Transient electronic structure probed by trARPES

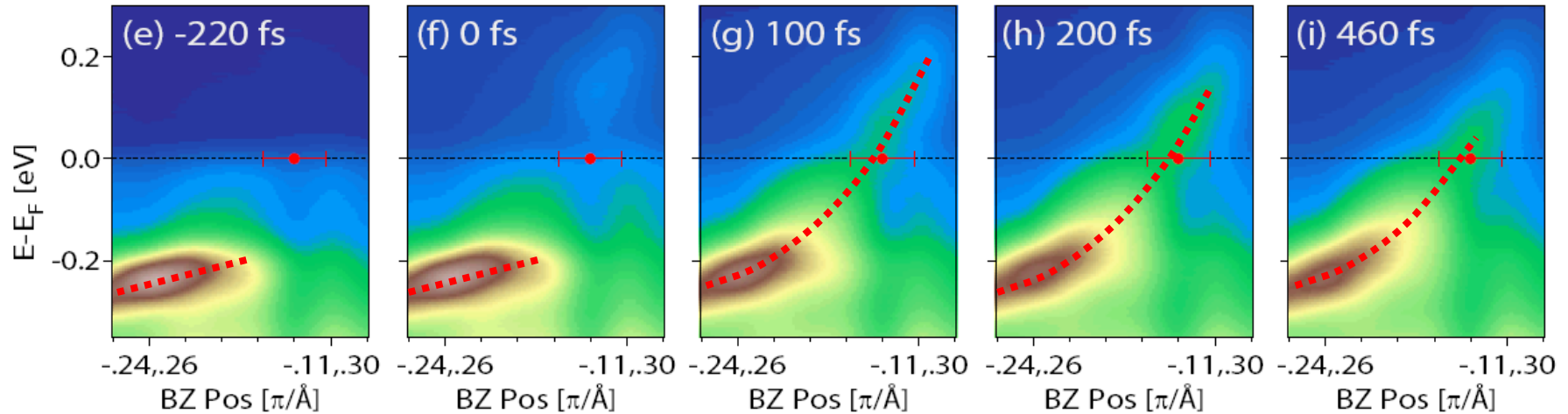
Goal: Probe dynamics of electronic structure directly by time-resolved ARPES



F. Schmitt *et al.*,
Science **321**, 1649 (2008)

Ultrafast electronic melting of CDW state: TbTe_3

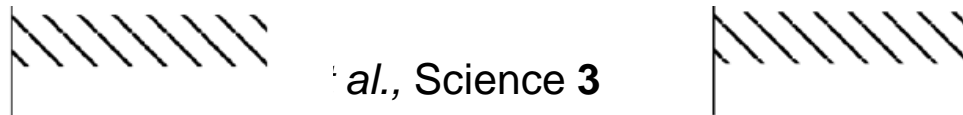
► Snapshots of electronic structure $E(k)$ at different time delays:



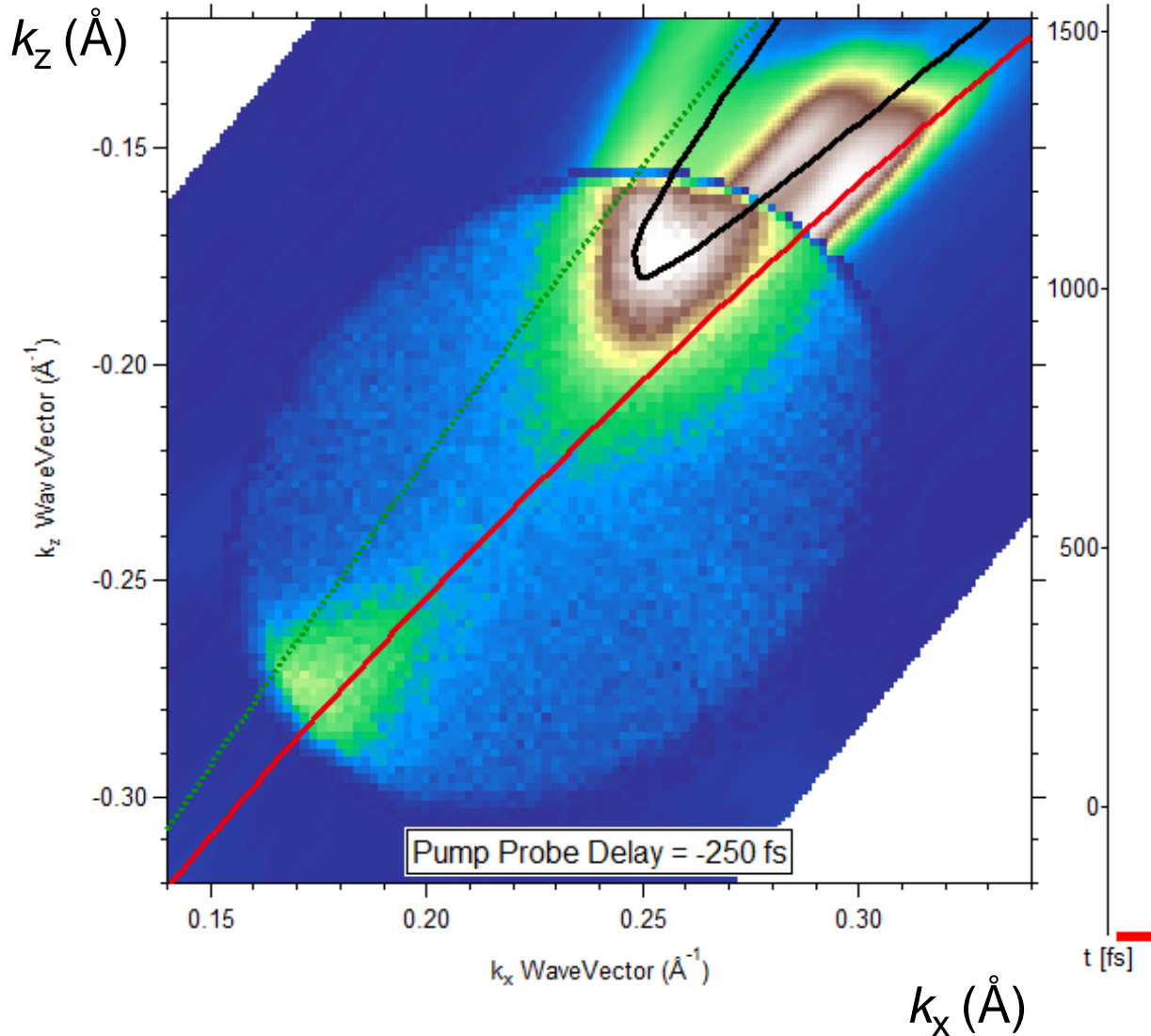
► Delayed collapse of CDW gap (>100 fs) after photodoping

- CDW transition requires **nuclear motion** \rightarrow excitation of amplitude mode
- Dynamics of photoinduced transition implies a “Peierls type” scenario

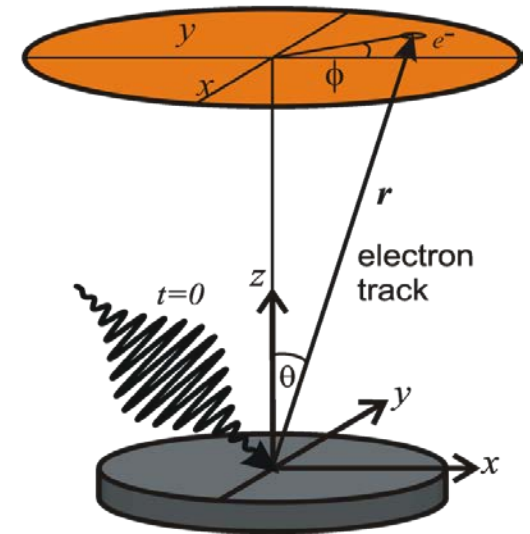
Can we directly measure the order parameter (gap size) ?



Time-resolved Fermi surface: DyTe₃



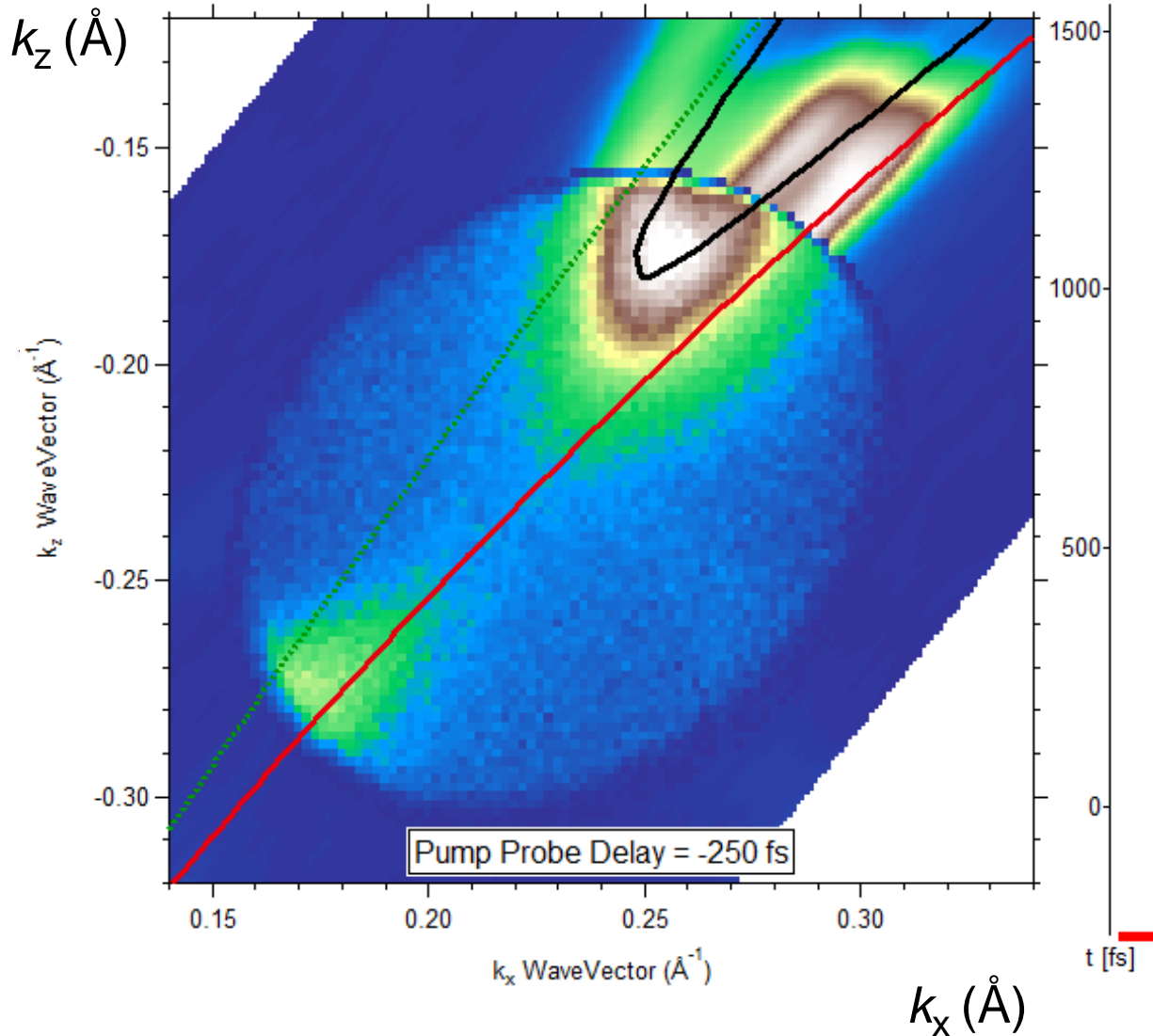
- Gapped area and metallic pocket well resolved with pTOF
- Excellent agreement with 7eV ARPES data and tight-binding model



Appl. Phys A **91**, 211 (2008)

Simultaneous mapping of k_x , k_y , E_{kin} versus time delay Δt

Time-resolved Fermi surface: DyTe₃



- Gapped area and metallic pocket well resolved with pTOF
- Excellent agreement with 7eV ARPES data and tight-binding model

Dynamics:

- Collapse of the large gap within ~ 150 fs
- Recovery of metallic Fermi surface (FS)
- Heavy oscillations of intensity near FS

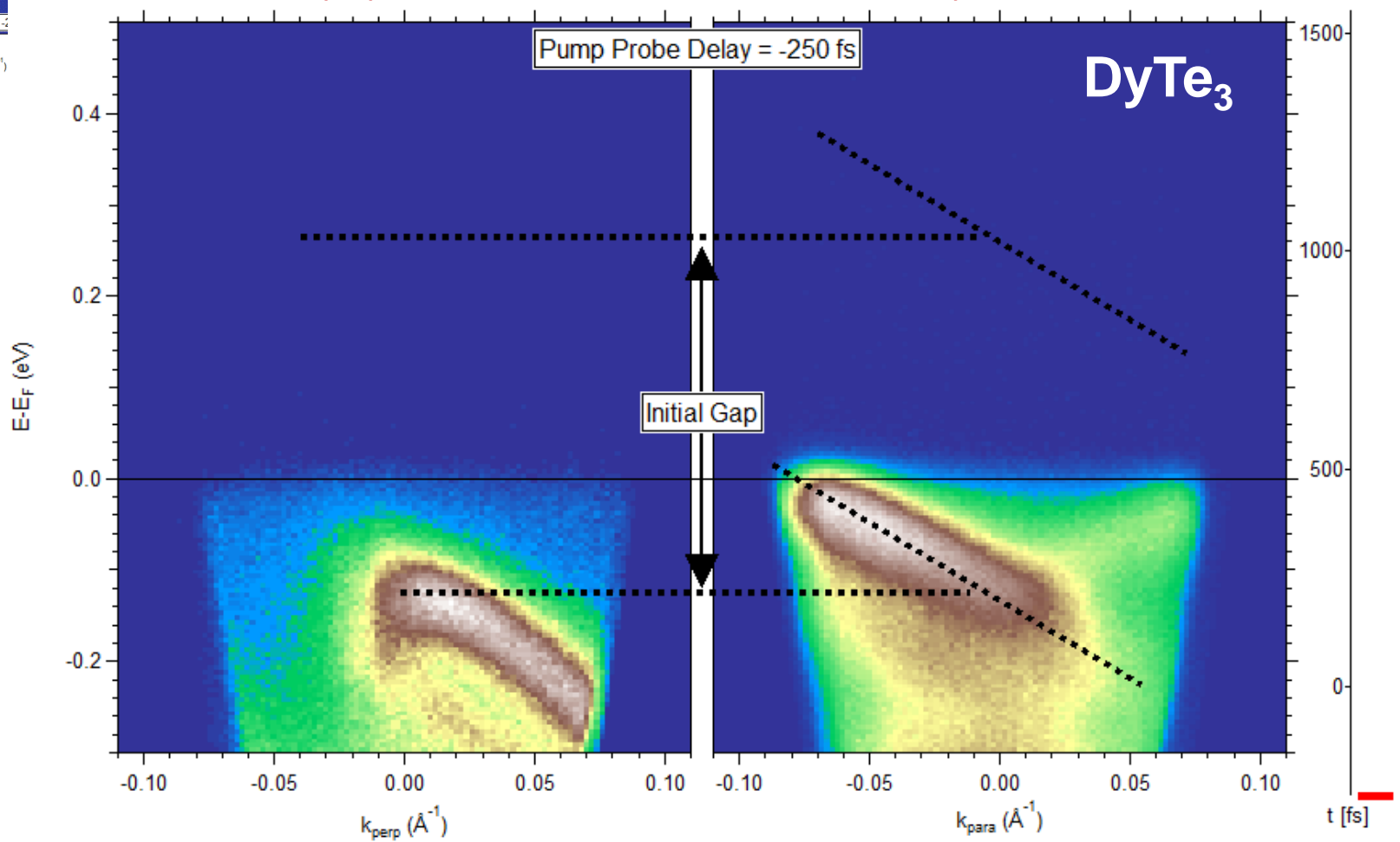
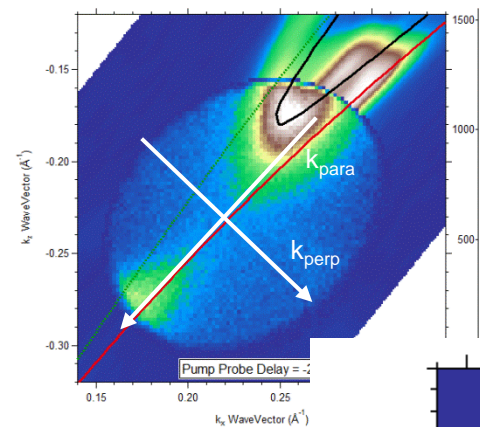
Simultaneous mapping of k_x , k_y , E_{kin} versus time delay Δt

Dynamics along the Fermi surface

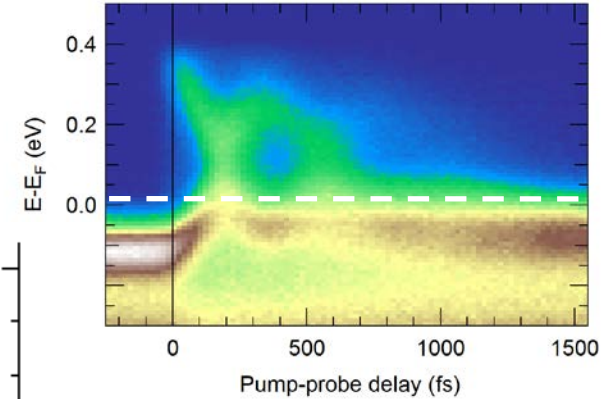
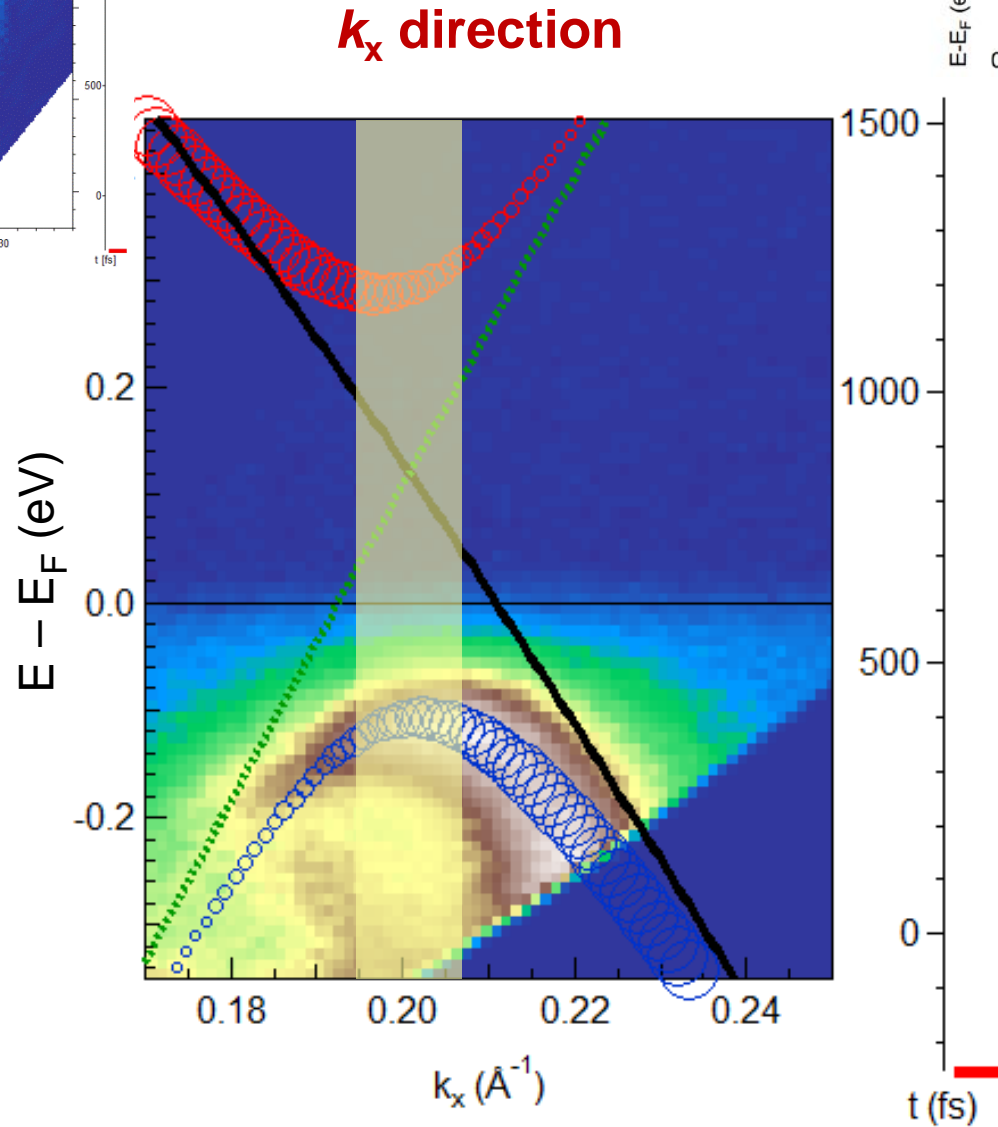
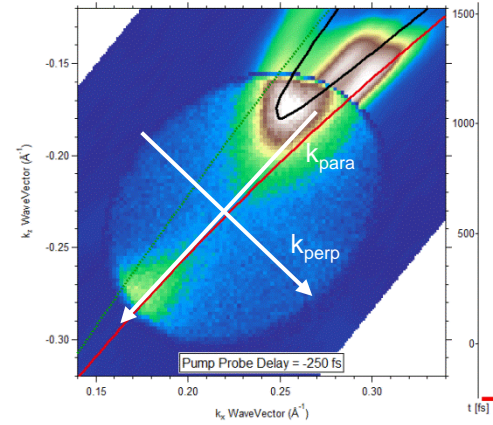
- ▶ Transient electronic bandstructure near the gap:
Dynamics of occupied and unoccupied bands

$k_{\text{perpendicular}}$

k_{parallel}



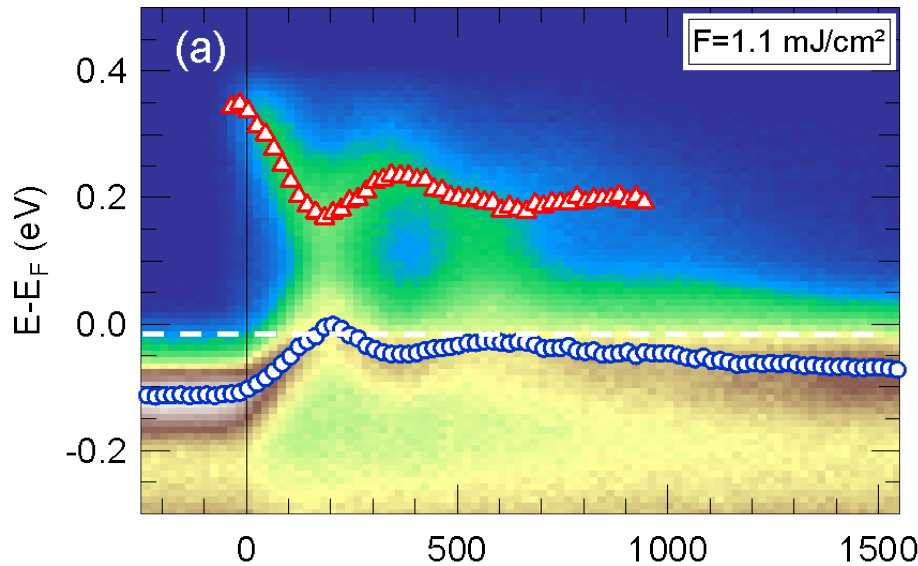
Dynamics of the gapped region: DyTe₃



- Population of the unoccupied upper CDW band
- Collaps of CDW gap within ~ 200 fs
- Transient formation of continuous “metallic” band dispersion
- Fitting to tight binding band structure

t (fs)

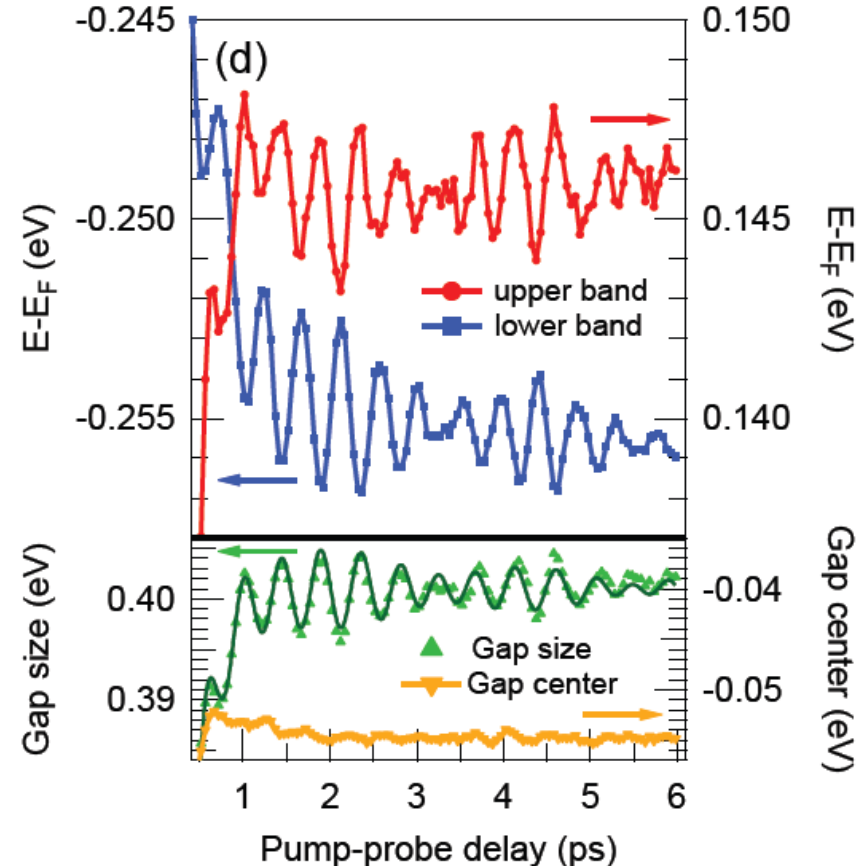
Dynamics of the CDW band gap



Conclusion:

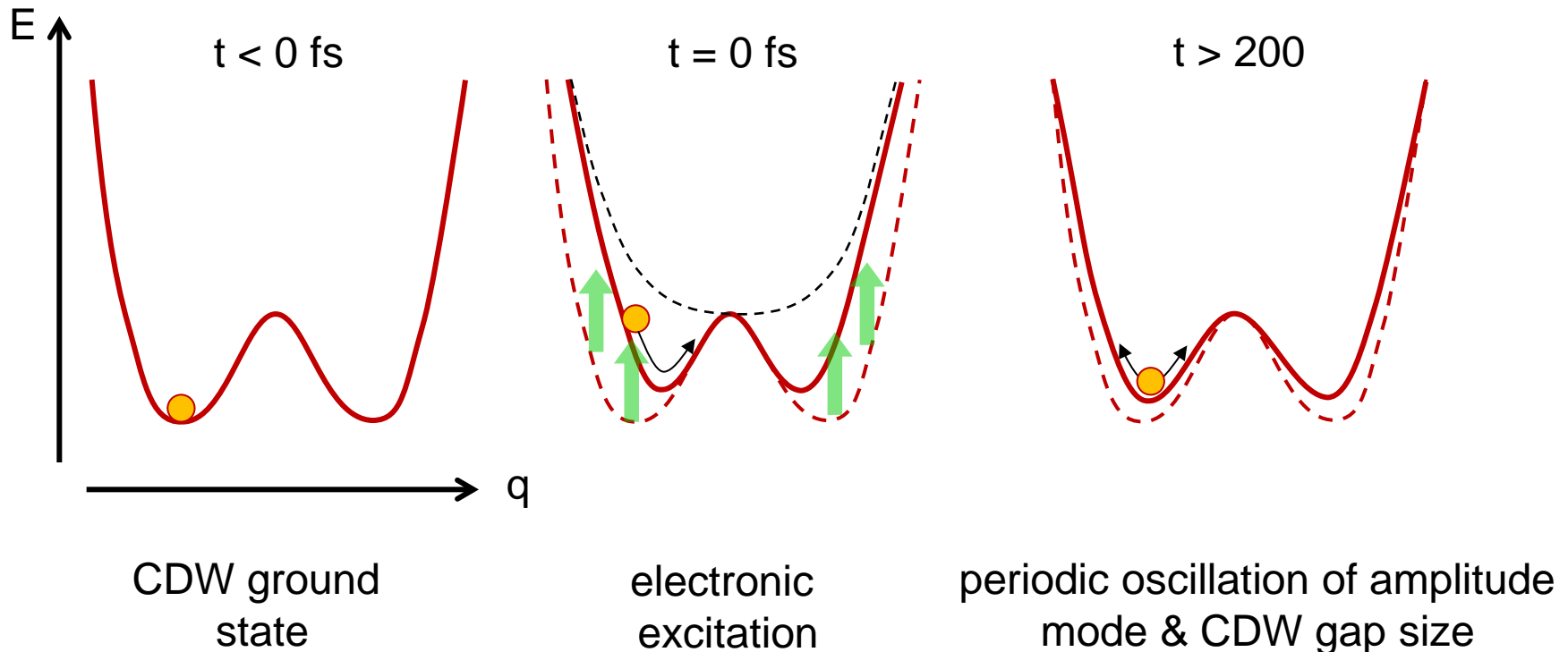
- **Insulator-to-metal transition** (lower CDW band shifts above E_F)
- At least **two phonon modes** modulate the CDW gap indicating a complex dynamics in the excited state.)

- Transient evolution of the lower and upper CDW band
- Pronounced oscillations of the ions in potential of the excited CDW system: **amplitude mode**



Discussion: CDW amplitude mode

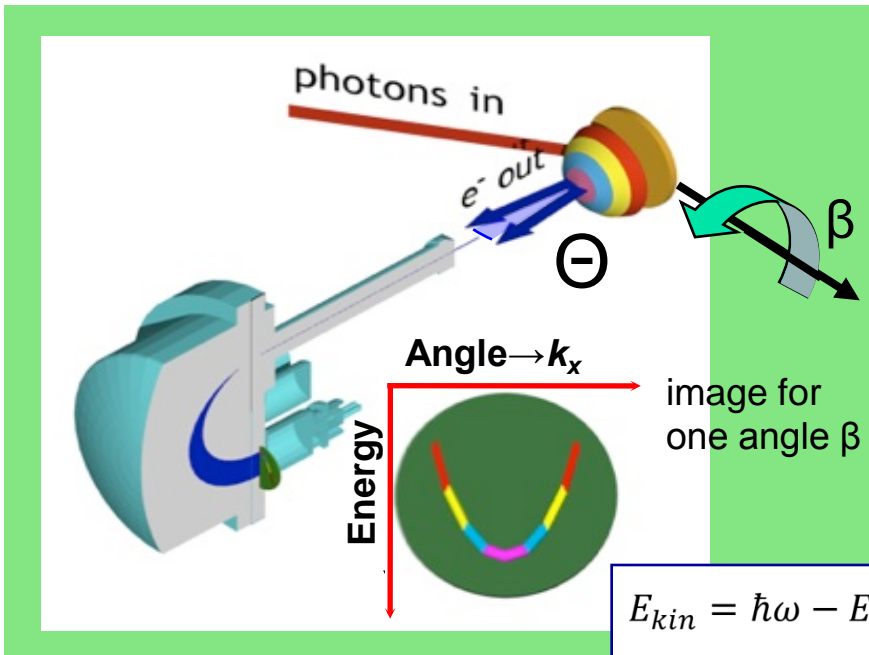
- Schematic sketch of the CDW potential energy surface



- CDW order parameter remains finite in photoexcited state
- Multiple phonon modes modulate the CDW gap

Probing the full Brillouin zone: XUV-based trARPES

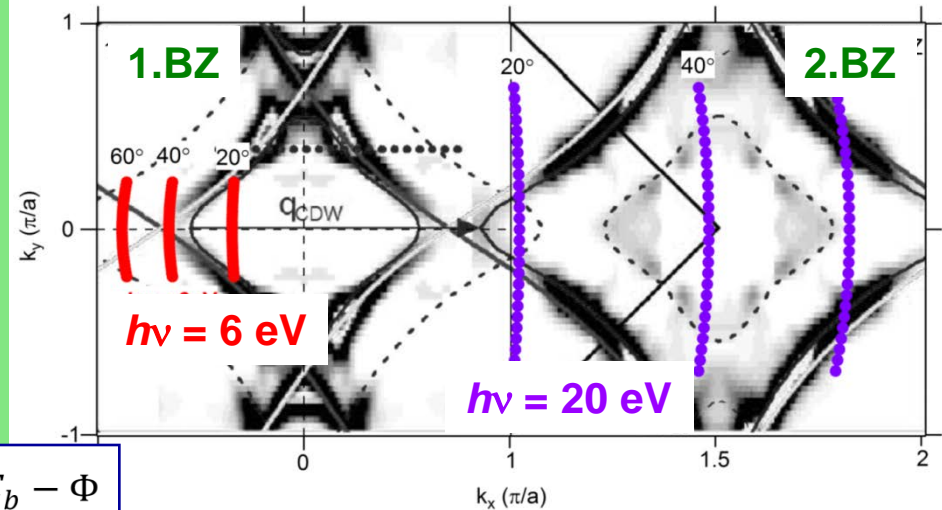
Goal: Probing transient electronic structure of solids throughout k-space



$$E_{kin} = \hbar\omega - E_b - \Phi$$

$$\hbar k = \sqrt{2m_e E_{kin}}$$

k-space access to full Brillouin zone

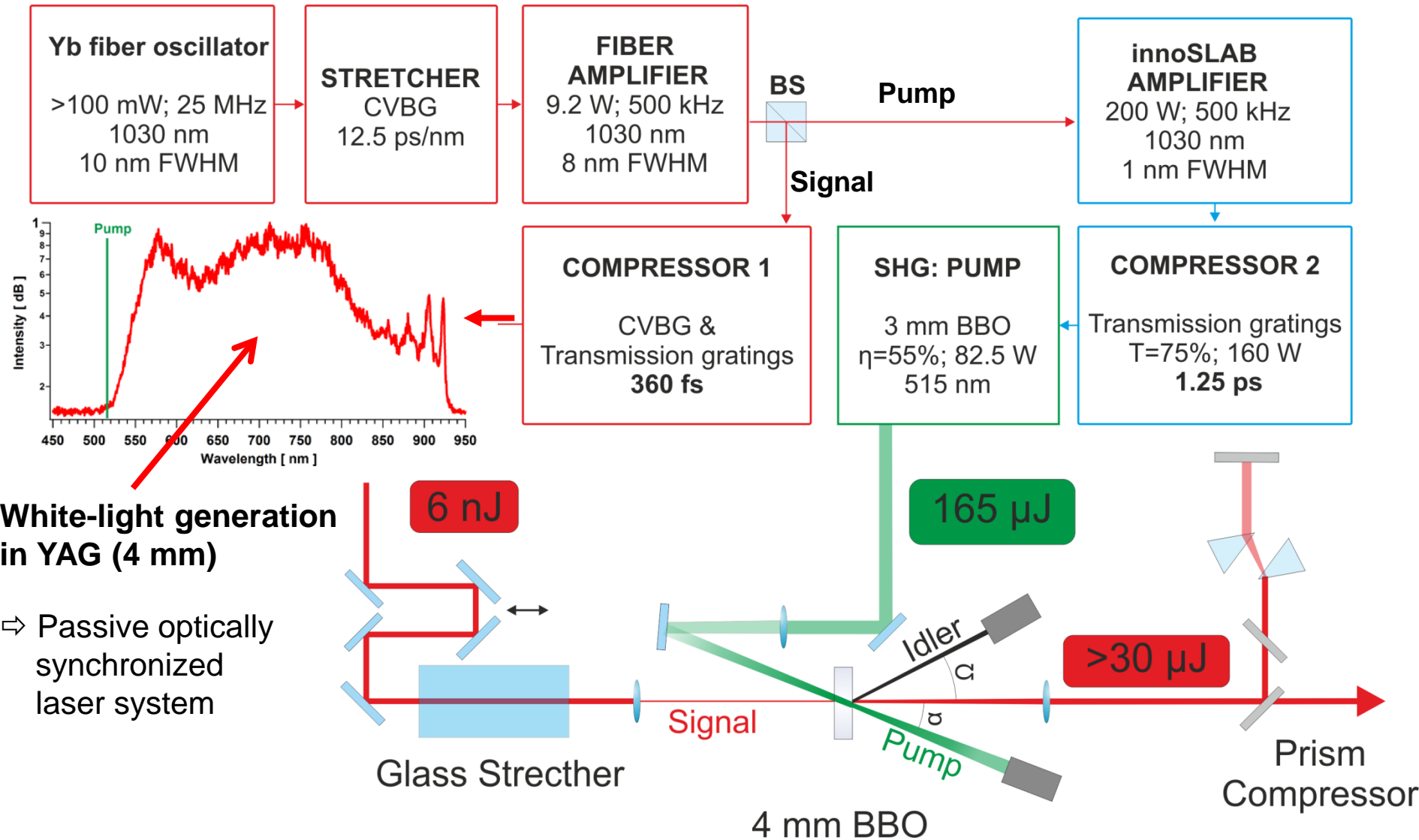


k-space access exemplified for CeTe₃ at $h\nu = 6$ eV and $h\nu = 20$ eV.

Desired parameters of trARPES photon source:

- Sufficient photon energy to **access full Brillouin zone**, i.e. $h\nu > 10$ eV
- High repetition rate providing **good counting statistics**, i.e. > 100 kHz
- **Time resolution**: from few fs to several 10 fs pulse duration
- Flexibility in time-bandwidth product: **Adapted** energy resolution

Development of 500 kHz OPCPA System

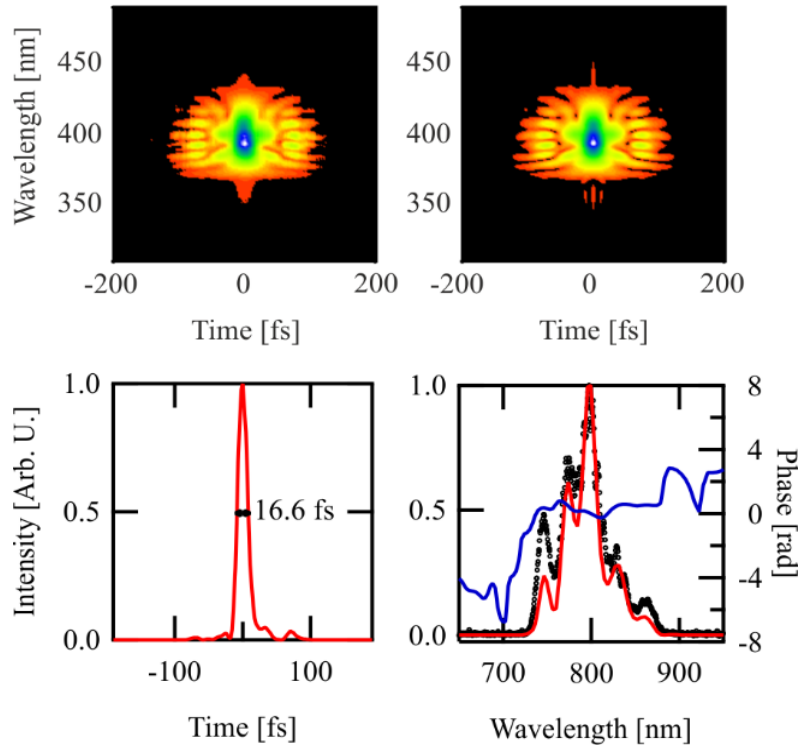


Puppin *et al.*, Opt. Expr. 23, 1491 (2015)

Walk-off compensated configuration

Development of 500 kHz OPCPA System

Compressed OPCPA output:



Prism
Compressor

20 W @
500 kHz
(**40 μ J**)
@ 790 nm

< 20 fs

Power
stability
0.3 %/hr

Pump

innoSLAB
AMPLIFIER
200 W; 500 kHz
1030 nm
1 nm FWHM

HG: PUMP

4 mm BBO
55%; 82.5 W
515 nm

COMPRESSOR 2

Transmission gratings
T=75%; 160 W
1.25 ps

165 μ J

synchronized
laser system

Glass Stretcher

Signal

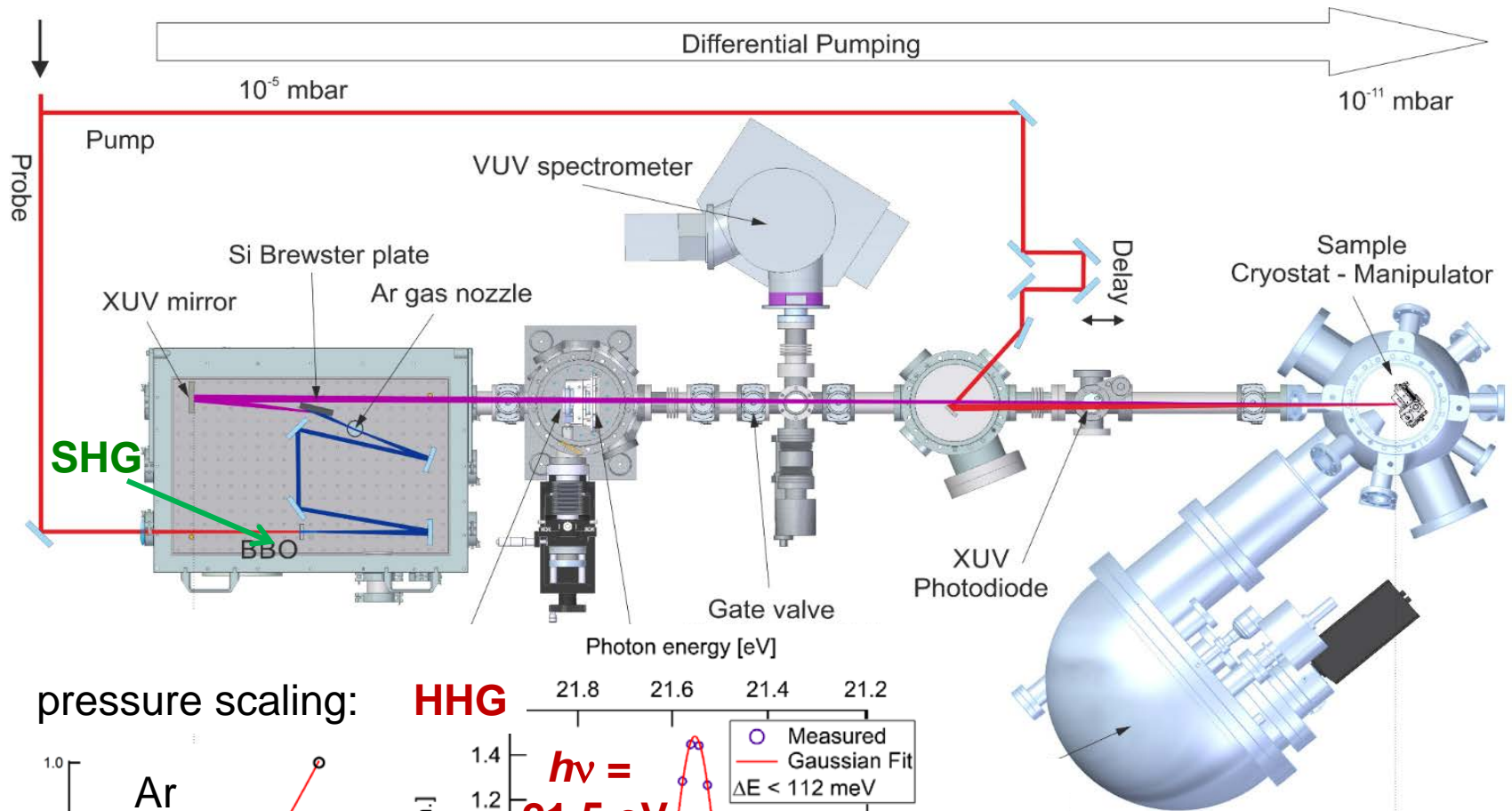
Pump

4 mm BBO

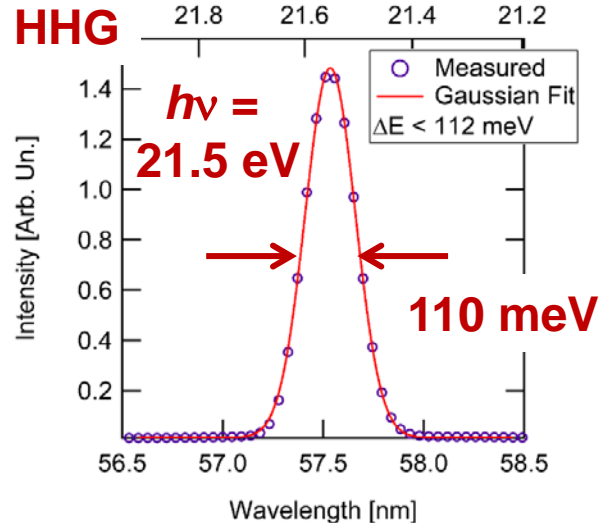
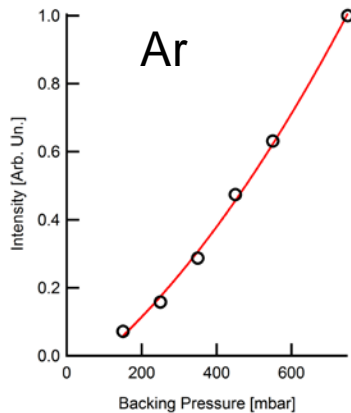
>30 μ J

Prism
Compressor

XUV-based time-resolved ARPES setup



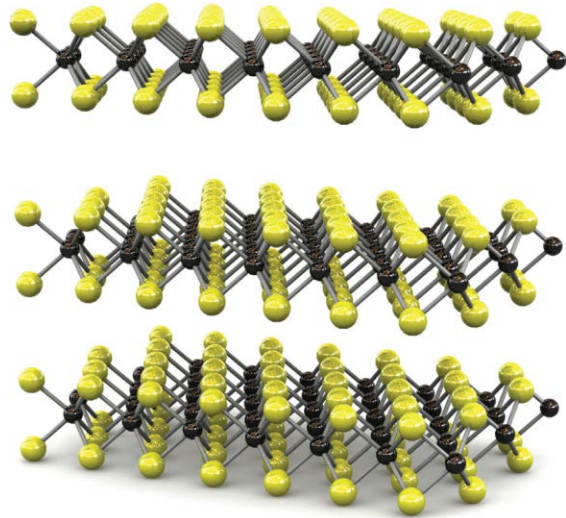
pressure scaling:



400 nm-driven HHG in Ar:
 7th harmonic (at 21.5 eV)
>10¹¹ photons/s at sample
 within ~100 meV bandwidth

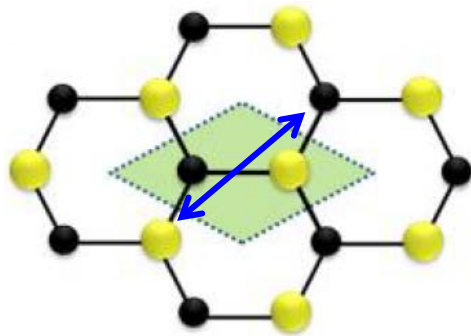
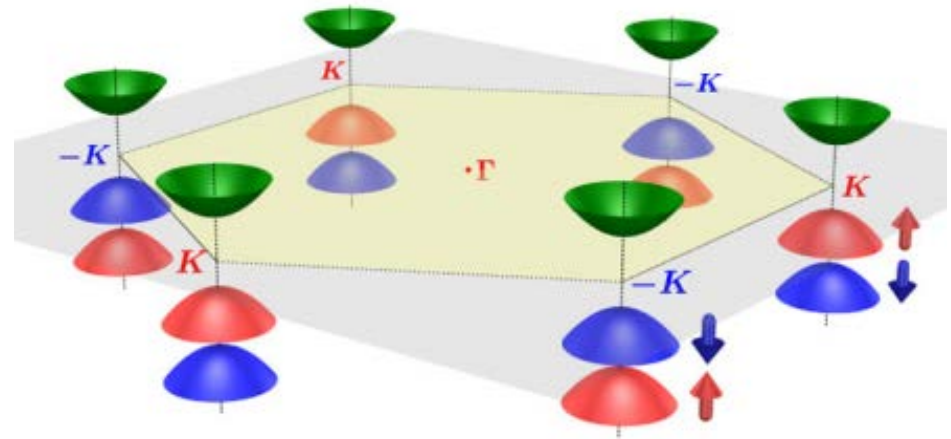
Semiconducting transition metal dichalcogenides

General characteristics: layered crystals, about 40 different TMDCs



Examples:

- MoS_2
- WSe_2



No intra-layer
inversion symmetry

Pronounced excitonic effects:

- up to several 100 meV binding energy for freestanding monolayers

Pronounced spin-orbit splitting:

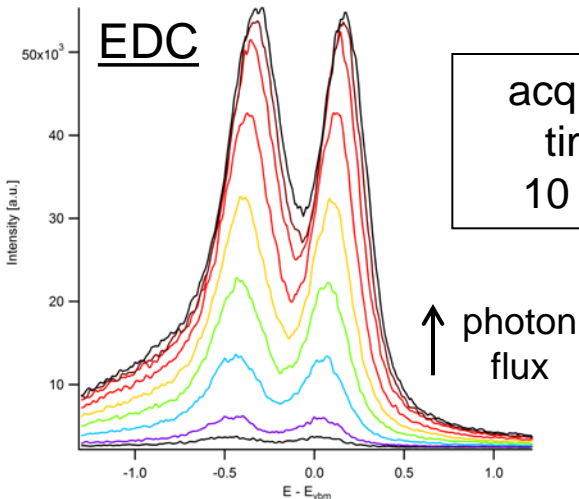
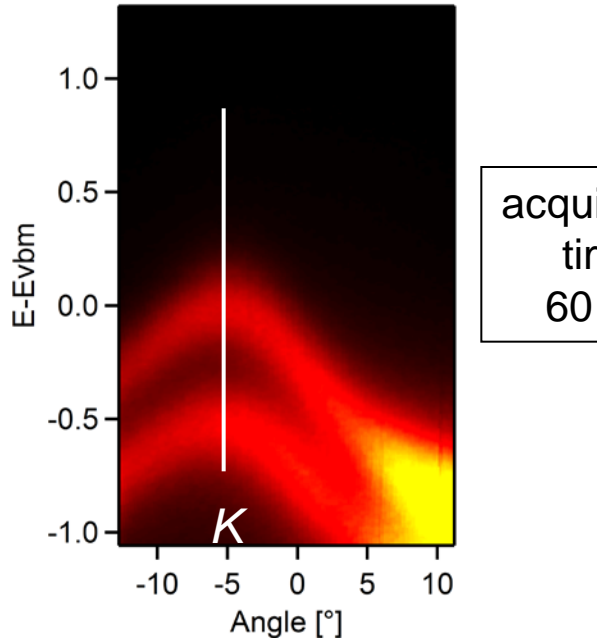
- up to 500 meV spin splitting in valence band

Peculiar electronic structure:

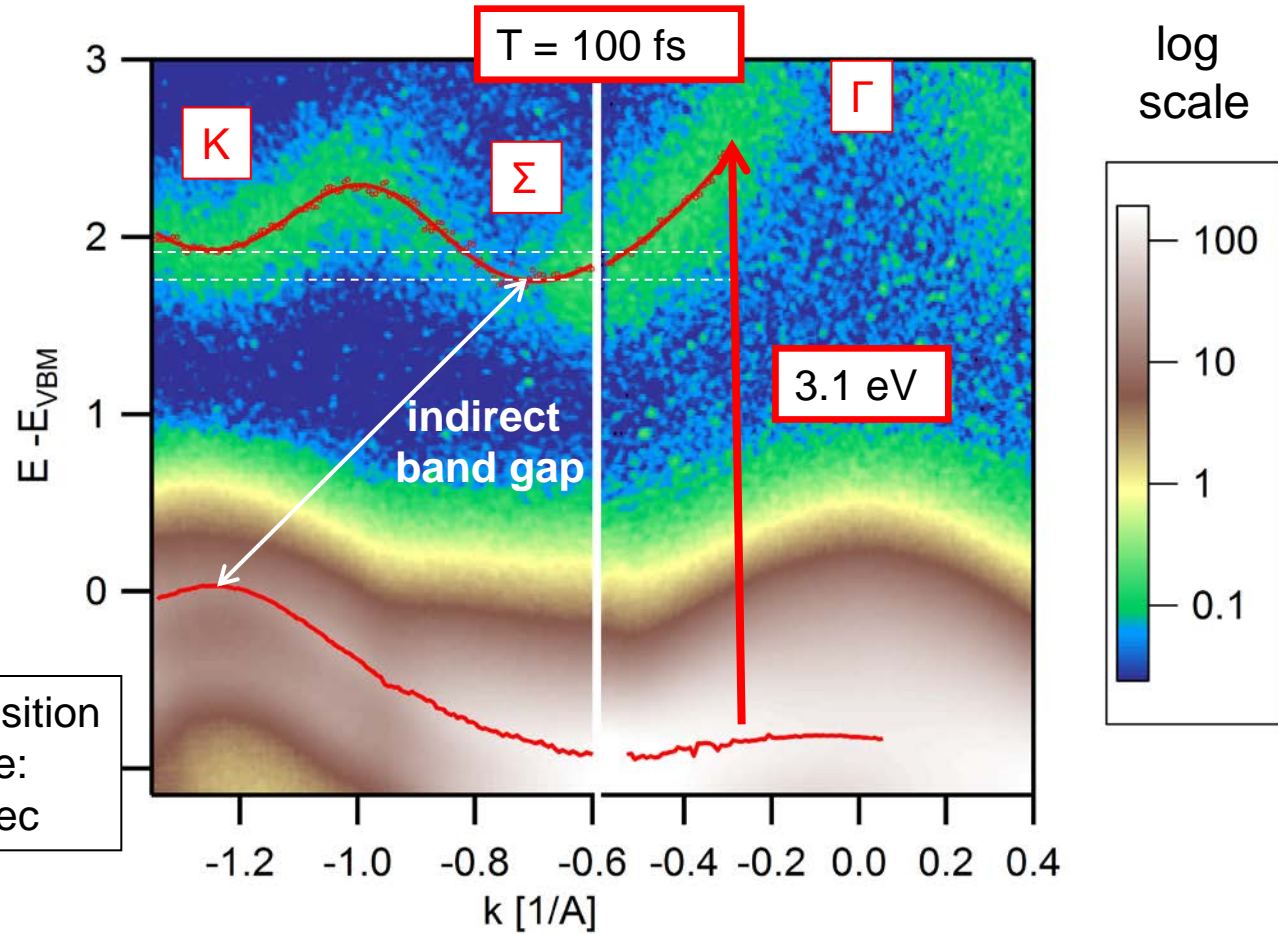
- spin-, valley- and layer degrees of freedom
- pronounced k -dependence

500 kHz HHG-based ARPES

Occupied bands, K valley WSe₂



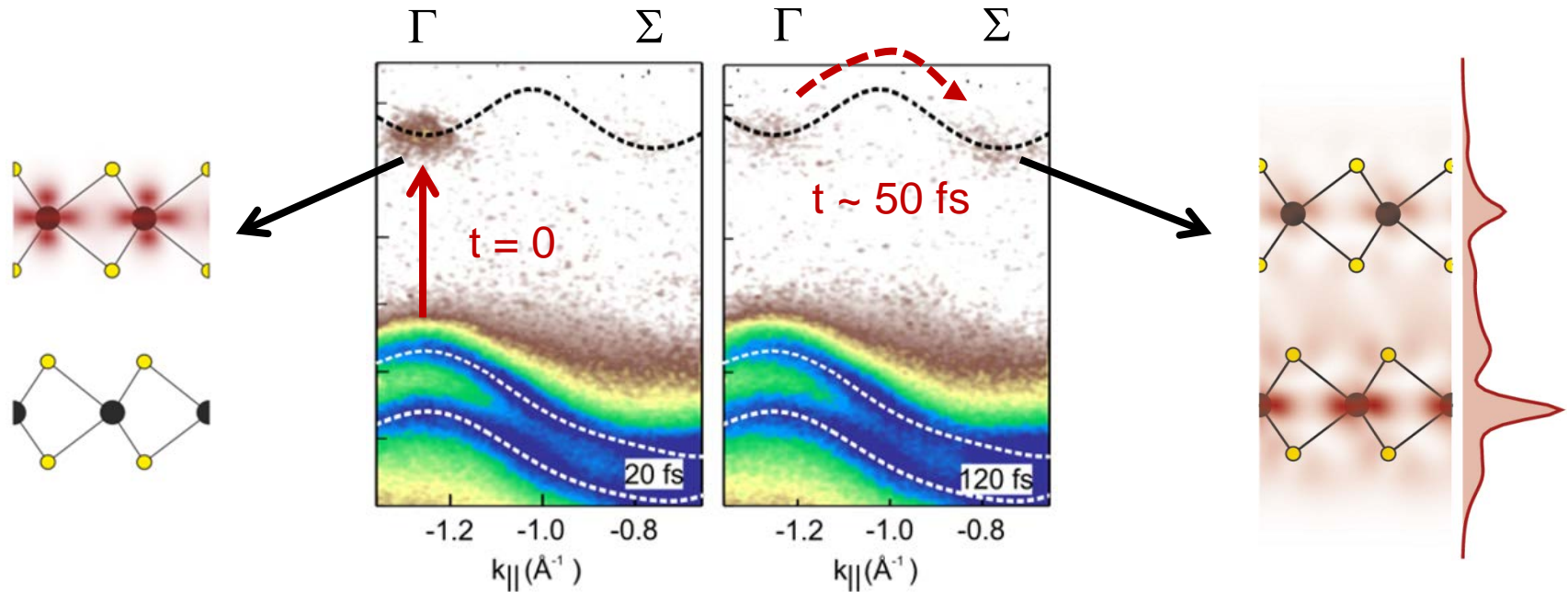
Excited state mapping in WSe₂ ($\Delta t = 50$ fs, 3 eV pump, "full k-space")



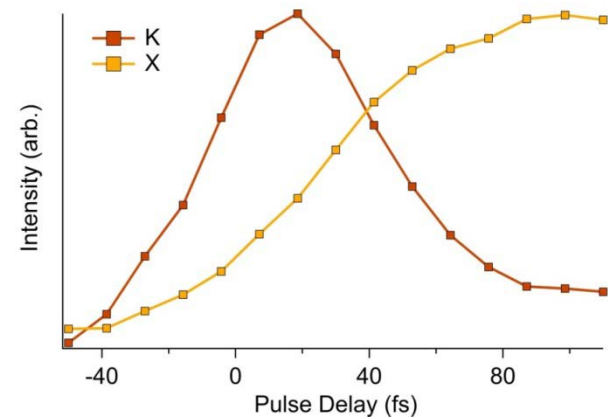
Direct mapping of conduction band
(excited states)

Excited state dynamics in WSe₂

Projection of spin-, valley- and layer-polarization on excited states



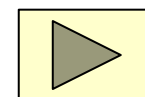
- Intervalley scattering transfers population from 2D to 3D states.
- These states govern interlayer coupling, transport, ...



Ultrafast surface chemistry Probing chemical bond formation at surfaces by femtosecond x-ray spectroscopy

Dell'Angela *et al.*, *Science* **339**, 1302 (2013)

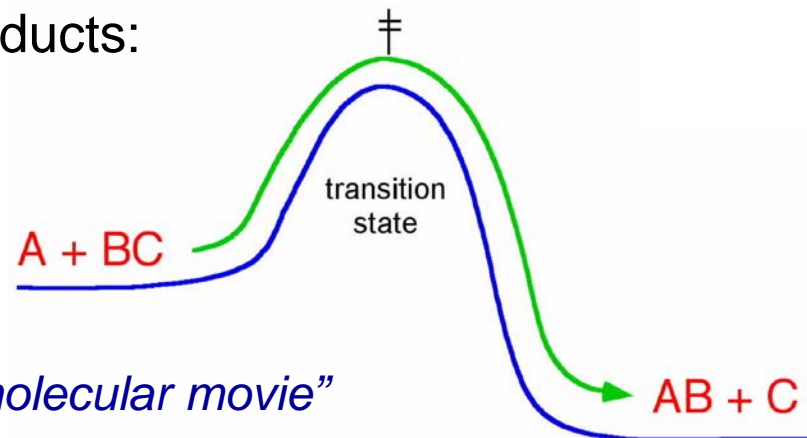
H. Öström *et al.*, *Science* **347**, 978 (2015)



Dynamics of chemical reactions

Temporal evolution from reactants to products:

- Dynamics of the transition state
- Key concept: Born-Oppenheimer potential energy surface
- Molecular dynamics simulations: “molecular movie”



However, the forces originate from the electronic structure !

Open questions:

- Dynamics of the electronic structure associated with the nuclear motion
- Non-adiabatic coupling between electronic states (e.g. at conical intersections)

Movie of transient electronic structure

Goal: Microscopic understanding of reaction dynamics

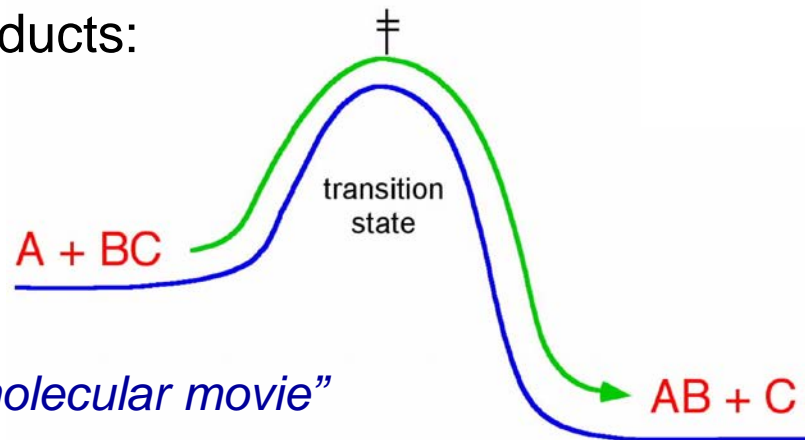
Dynamics of chemical reactions

Temporal evolution from reactants to products:

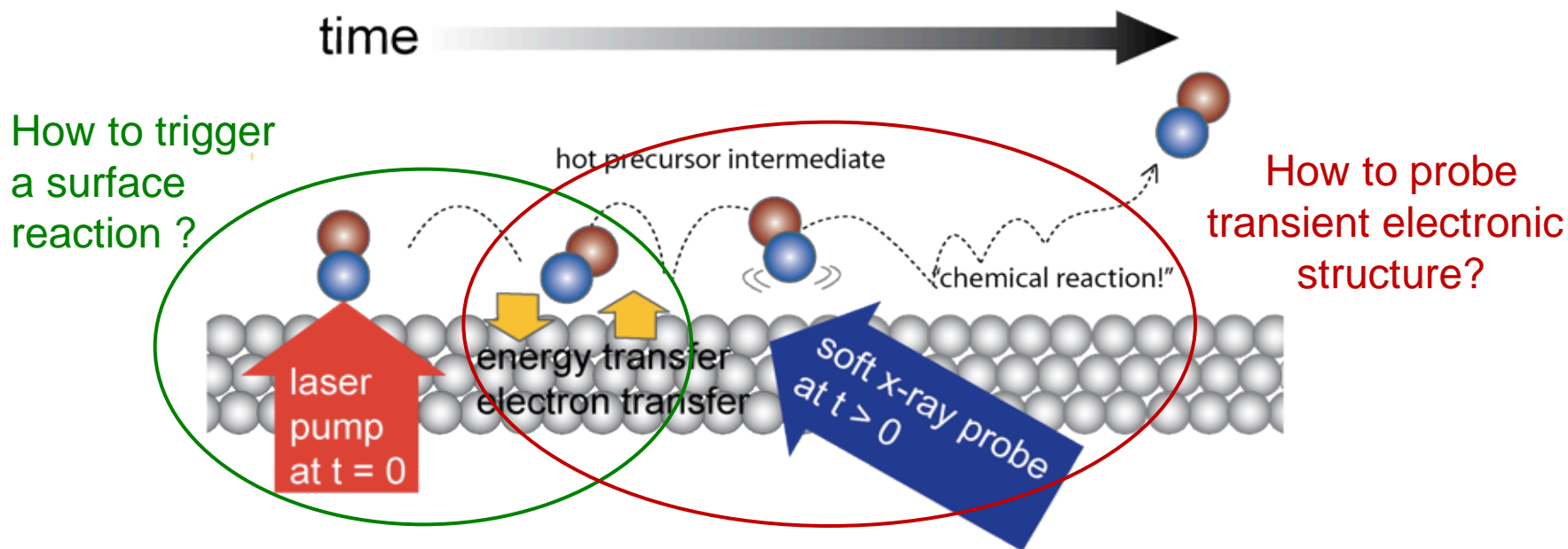
→ Dynamics of the transition state

→ Key concept: Born-Oppenheimer potential energy surface

→ Molecular dynamics simulations: *"molecular movie"*

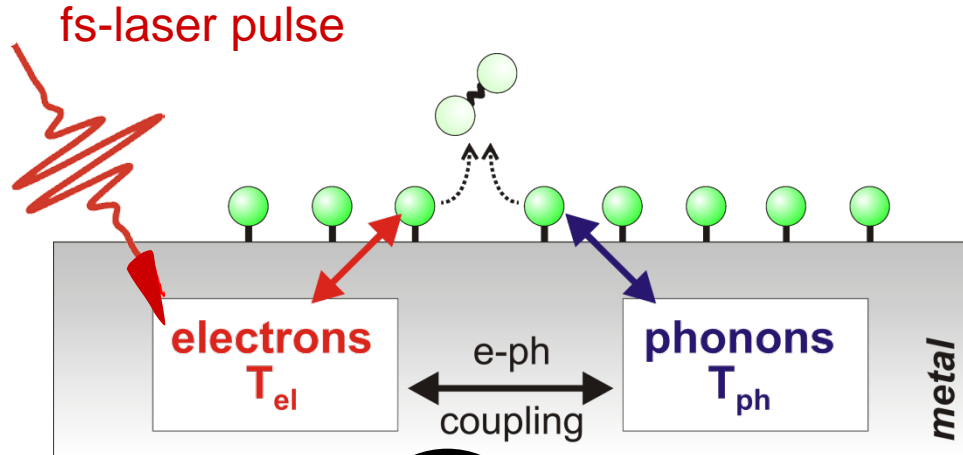


Goal: Evolution of the **transient electronic structure**, e.g. during a surface reaction

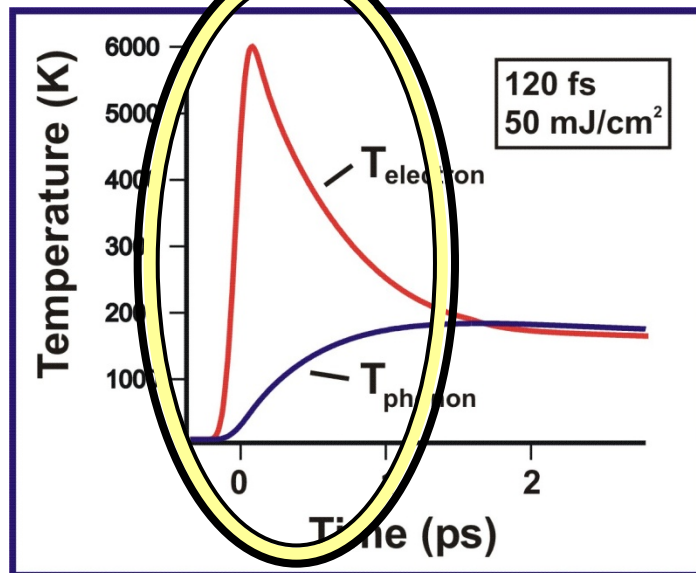


Femtochemistry at metal surfaces

Ultrafast energy redistribution after optical excitation of a metal surface



- monolayer is optical thin
- substrate-mediated excitations dominate



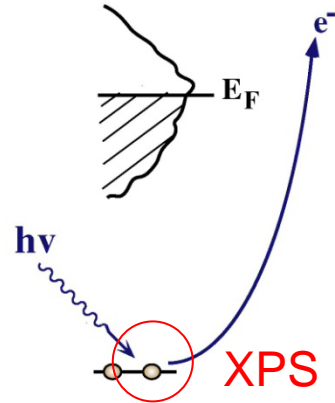
transient non-equilibrium
with $T_{el} \gg T_{ph}$

coupling to adsorbate
vibrations induces reaction

reaction driven by **electrons**
(fast) or **phonons** (slow)

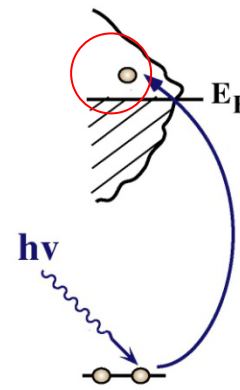
Photon in – photon out methods: X-ray emission

X-ray photoemission (XPS)

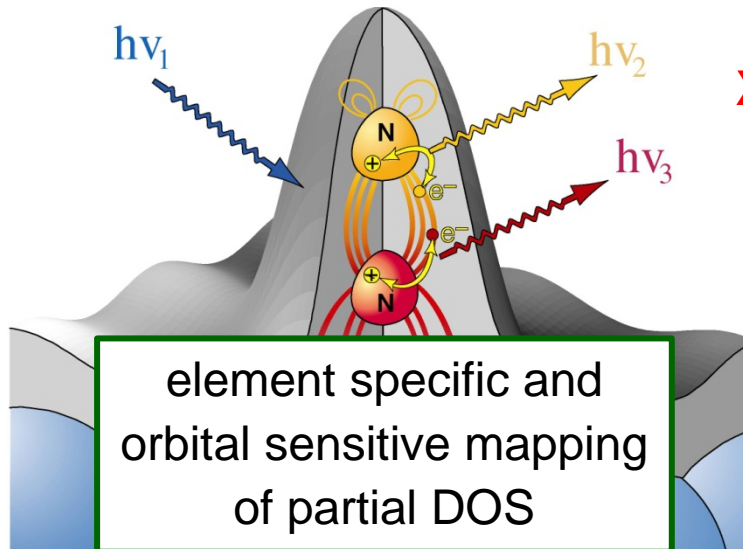


Probe chemical state

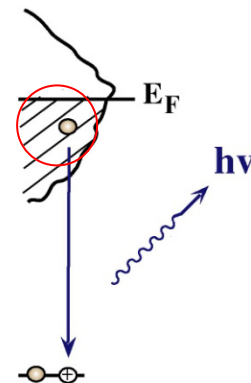
X-ray absorption (XAS)



unoccupied valence state

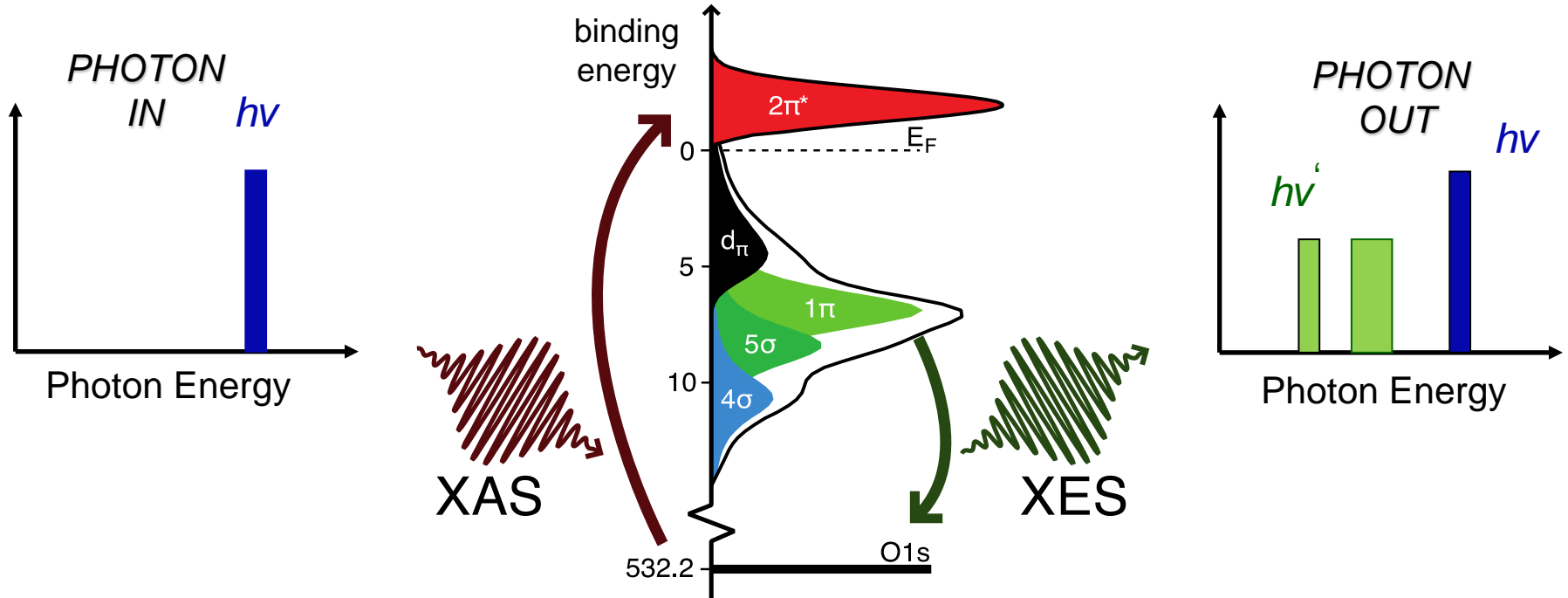


X-ray emission (XES)

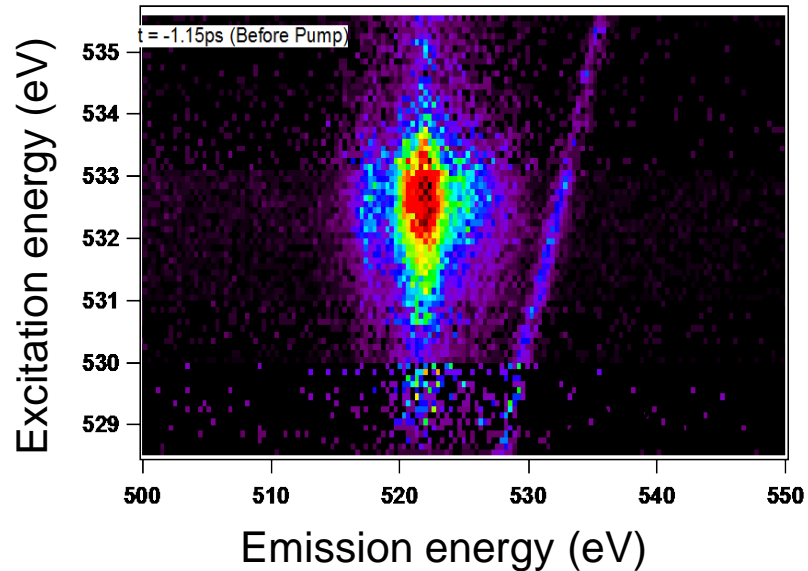


occupied valence state

Resonant inelastic X-ray scattering (RIXS)

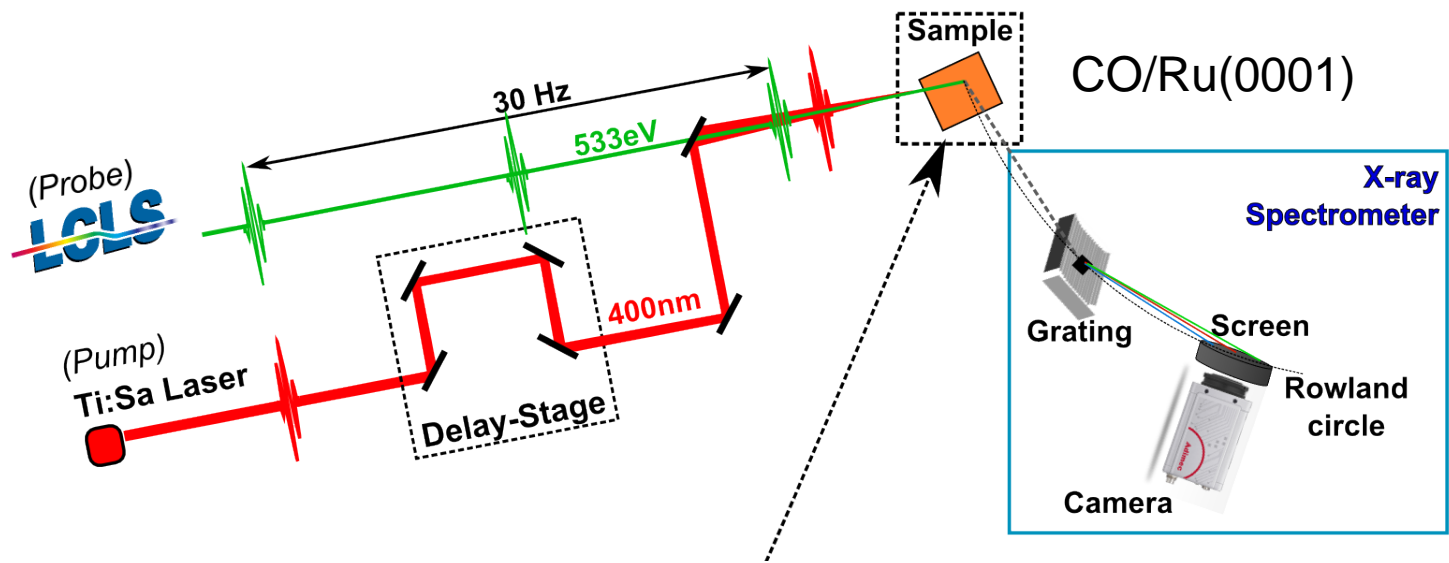


scan excitation energy

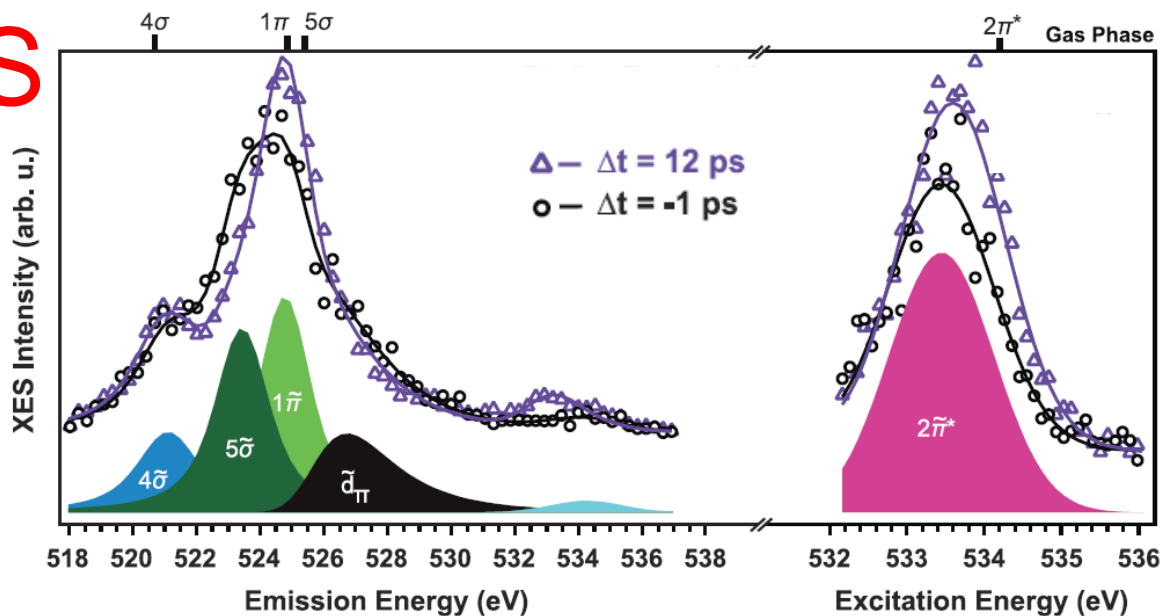


probe x-ray emission energy

Time-resolved RIXS of laser-excited CO/Ru(0001)



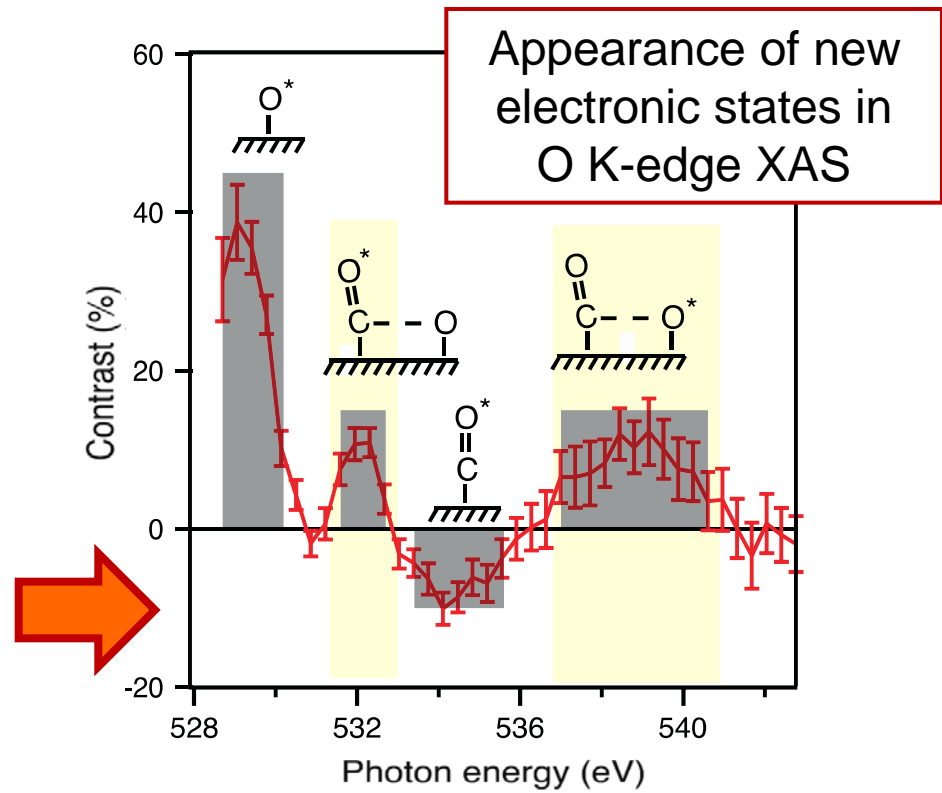
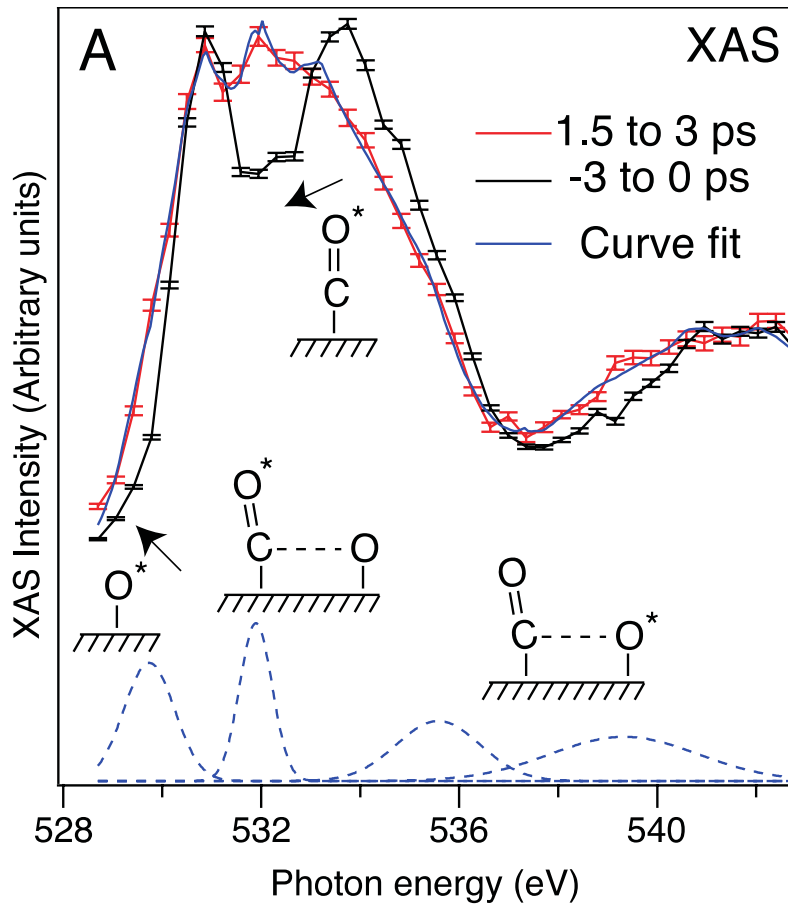
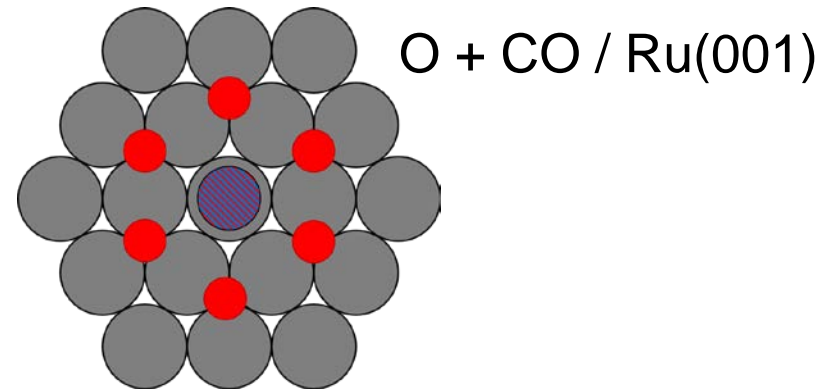
XES



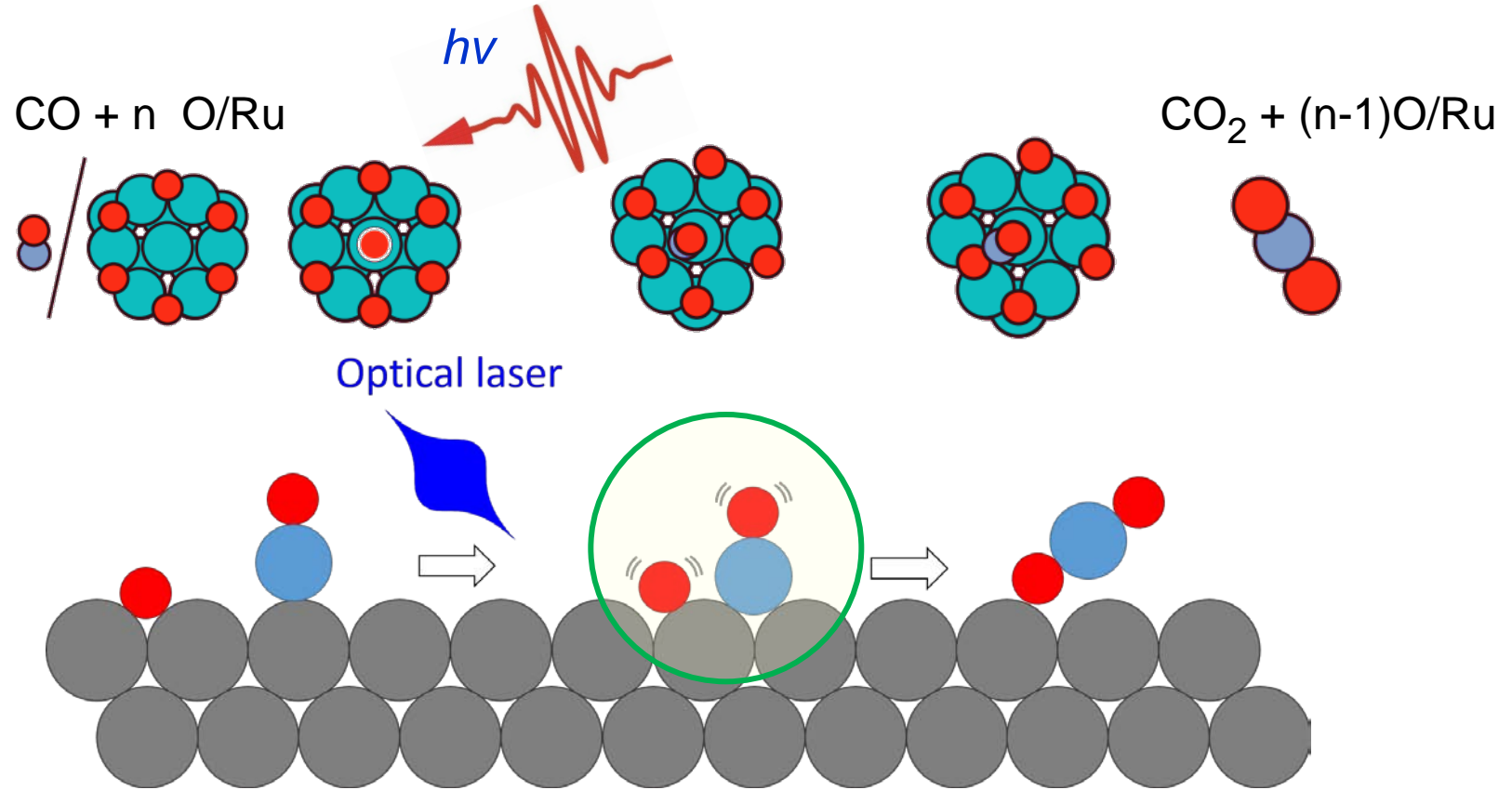
XAS

Dell'Angela *et al.*
 Science **339**, 1302
 (2013)

fs-laser-induced CO oxidation probed by trXAS



Summary: Dynamics of CO oxidation



- ➔ Both O and CO are excited and „collide“ in reactive adlayer during CO_2 formation: **Formation of transient OC–O species**
- ➔ Distribution of OC–O bond lengths close to transition state
- ➔ Transition state region is, *Science* **317**, 978 (2016) previously believed

- Various elementary processes in physics, chemistry, biology occur on femtosecond time scales.
- Femtosecond laser pulses exhibit unique properties for metrology of light, non-linear optics, ultrafast spectroscopy & more.
- Examples:
 - Time-domain THz spectroscopy of photoexcited carriers.
 - THz pumping of low frequency modes (magnons, phonons)
 - ⇒ an unconventional way to couple energy into the system
 - Dynamics of electronic band structure in solids probed by trARPES
- There exists a large toolbox to induce and probe ultrafast dynamics in solids and at interfaces (THz to x-rays, electrons,...)
- These tool have specific strengths, but also limits...